



## MIC2164/-2/-3/C

Synchronous Buck Controllers  
Featuring Adaptive On-Time Control  
28V Input, Constant Frequency

Hyper Speed Control™ Family

### General Description

The Micrel MIC2164/-2/-3/C are constant-frequency, synchronous buck controllers featuring adaptive on-time control. The MIC2164/-2/-3/C are the first products in the new Hyper Speed Control™ family of buck controllers introduced by Micrel.

The MIC2164/-2/-3/C controllers operate over an input supply range of 3V to 28V, and are independent of the IC supply voltage. The devices are capable of supplying 25A output current. While the MIC2164 operates at 300kHz, the MIC2164-2 operates at 600kHz, and the MIC2164-3 operates at 1MHz.

A unique Hyper Speed Control™ architecture allows for ultra-fast transient response while reducing the output capacitance and also makes High  $V_{IN}$ /Low  $V_{OUT}$  operation possible. The MIC2164/-2/-3/C controllers utilizes an architecture which is adaptive  $T_{ON}$  ripple controlled. A UVLO feature is provided to ensure proper operation under power-sag conditions to prevent the external power MOSFET from overheating. A soft start feature is provided to reduce the inrush current. Foldback current limit and “hiccup” mode short-circuit protection ensure FET and load protection.

The MIC2164/-2/-3/C controllers are available in a 10-pin MSOP (MAX1954A-compatible) package with a junction operating range from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

All support documentation can be found on Micrel's web site at: [www.micrel.com](http://www.micrel.com).

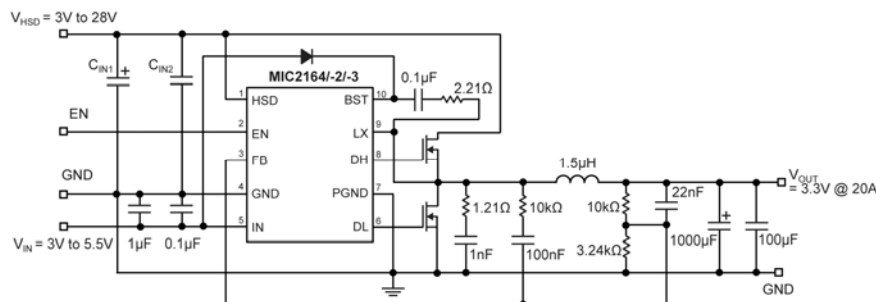
### Features

- Hyper Speed Control™ architecture enables
  - High delta V operation ( $V_{HSD} = 28\text{V}$  and  $V_{OUT} = 0.8\text{V}$ )
  - Smaller output capacitors than competitors
- 3V to 28V input voltage
- Any Capacitor™ stable
  - Zero ESR to high ESR
- 25A output current capability
- 300kHz/600kHz/1MHz switching frequency
- Adaptive on-time mode control
- Adjustable output from 0.8V to 5.5V with  $\pm 1\%$  (MIC2164/-2/-3) or  $\pm 3\%$  (MIC2164C) FB accuracy
- Up to 95% efficiency
- Foldback current-limit and “hiccup” mode short-circuit protection
- 6ms Internal soft start
- Thermal shutdown
- Safe start-up into pre-biased loads
- $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  junction temperature range
- Available in 10-pin MSOP package

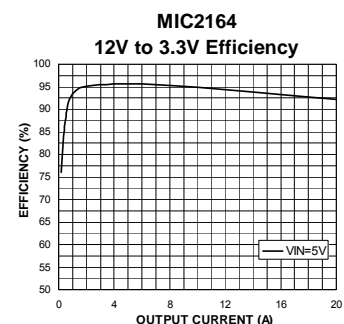
### Applications

- Set-top box, gateways and routers
- Printers, scanners, graphic cards and video cards
- Telecommunication, PCs and servers

### Typical Application



MIC2164/-2/-3/C Synchronous Controllers Featuring Adaptive On-Time Control



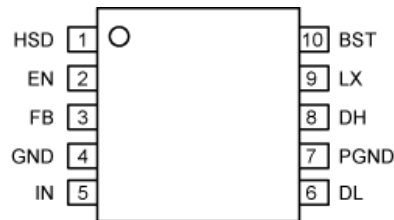
Hyper Speed Control and Any Capacitor is a trademark of Micrel, Inc.

Micrel Inc. • 2180 Fortune Drive • San Jose, CA 95131 • USA • tel +1 (408) 944-0800 • fax + 1 (408) 474-1000 • <http://www.micrel.com>

## Ordering Information

| Part Number  | Voltage    | Switching Frequency | Accuracy | Junction Temperature Range | Package     | Lead Finish |
|--------------|------------|---------------------|----------|----------------------------|-------------|-------------|
| MIC2164YMM   | Adjustable | 300kHz              | ±1%      | -40° to +125°C             | 10-pin MSOP | Pb-Free     |
| MIC2164-2YMM | Adjustable | 600kHz              | ±1%      | -40° to +125°C             | 10-pin MSOP | Pb-Free     |
| MIC2164-3YMM | Adjustable | 1MHz                | ±1%      | -40° to +125°C             | 10-pin MSOP | Pb-Free     |
| MIC2164CYMM  | Adjustable | 270kHz              | ±3%      | -40° to +125°C             | 10-pin MSOP | Pb-Free     |

## Pin Configuration



10-Pin MSOP (MM)

## Pin Description

| Pin Number | Pin Name | Pin Function  |
|------------|----------|---|
| 1          | HSD      | High-Side N-MOSFET Drain Connection (input): Power to the drain of the external high-side N-channel MOSFET. The HSD operating voltage range is from 3V to 28V. Input capacitors between HSD and the power ground (PGND) are required.   |
| 2          | EN       | Enable (input): A logic level control of the output. The EN pin is CMOS-compatible. Logic high or floating = enable, logic low = shutdown. In the off state, supply current of the device is greatly reduced (typically 0.8mA).   |
| 3          | FB       | Feedback (input): Input to the transconductance amplifier of the control loop. The FB pin is regulated to 0.8V. A resistor divider connecting the feedback to the output is used to adjust the desired output voltage.  |
| 4          | GND      | Signal ground. GND is the ground path for the device input voltage $V_{IN}$ and the control circuitry. The loop for the signal ground should be separate from the power ground (PGND) loop.   |
| 5          | IN       | Input Voltage (input): Power to the internal reference and control sections of the MIC2164/-2/-3. The IN operating voltage range is from 3V to 5.5V. A 1 $\mu$ F and 0.1 $\mu$ F ceramic capacitors from IN to GND are recommended for clean operation.   |
| 6          | DL       | Low-Side Drive (output): High-current driver output for external low-side MOSFET. The DL driving voltage swings from ground-to-IN.  |
| 7          | PGND     | Power Ground. PGND is the ground path for the MIC2164/-2/-3 buck converter power stage. The PGND pin connects to the sources of low-side N-Channel MOSFETs, the negative terminals of input capacitors, and the negative terminals of output capacitors. The loop for the power ground should be as small as possible and separate from the Signal ground (GND) loop. |
| 8          | DH       | High-Side Drive (output): High-current driver output for external high-side MOSFET. The DH driving voltage is floating on the switch node voltage (LX). It swings from ground to $V_{IN}$ minus the diode drop. Adding a small resistor between DH pin and the gate of the high-side N-channel MOSFETs can slow down the turn-on and turn-off time of the MOSFETs.    |

**Pin Description (Continued)**

| Pin Number | Pin Name | Pin Function   |
|------------|----------|--|
| 9          | LX       | Switch Node and Current Sense input: High current output driver return. The LX pin connects directly to the switch node. Due to the high speed switching on this pin, the LX pin should be routed away from sensitive nodes. LX pin also senses the current by monitoring the voltage across the low-side MOSFET during OFF time. In order to sense the current accurately, connect the low-side MOSFET drain to LX using a Kelvin connection. |
| 10         | BST      | Boost (output): Bootstrapped voltage to the high-side N-channel MOSFET driver. A Schottky diode is connected between the IN pin and the BST pin. A boost capacitor of 0.1 $\mu$ F is connected between the BST pin and the LX pin. Adding a small resistor in series with the boost capacitor can slow down the turn-on time of high-side N-Channel MOSFETs.   |

### Absolute Maximum Ratings<sup>(1)</sup>

|   |                                    |
|---|------------------------------------|
| IN, FB, EN to GND .....                     | -0.3V to +6V                       |
| BST to LX .....                             | -0.3V to +6V                       |
| BST to GND .....                            | -0.3V to +37V                      |
| DH to LX .....                              | -0.3V to (V <sub>BST</sub> + 0.3V) |
| DL, COMP to GND .....                       | -0.3V to (V <sub>IN</sub> + 0.3V)  |
| HSD to GND .....                            | -0.3V to 31V                       |
| PGND to GND .....                           | -0.3V to +0.3V                     |
| Junction Temperature .....                  | +150°C                             |
| Storage Temperature (T <sub>S</sub> ) ..... | -65°C to +150°C                    |
| Lead Temperature (soldering, 10sec) .....   | 260°C                              |

### Operating Ratings<sup>(2)</sup>

|  |                 |
|--|-----------------|
| Input Voltage (V <sub>IN</sub> ) .....                     | 3.0V to 5.5V    |
| Supply Voltage (V <sub>HSD</sub> ) .....                   | 3.0V to 28V     |
| Operating Temperature Range .....                          | -40°C to +125°C |
| Junction Temperature (T <sub>J</sub> ) .....               | -40°C to +125°C |
| Junction Thermal Resistance                                |                 |
| MSOP (θ <sub>JA</sub> ) .....                              | 130.5°C/W       |
| Continuous Power Dissipation (T <sub>A</sub> = 70°C) ..... | 421mW           |
| (derate 5.6mW/°C above 70°C)                               |                 |

### Electrical Characteristics<sup>(4)</sup>

V<sub>BST</sub> - V<sub>LX</sub> = 5V; T<sub>A</sub> = +25°C, unless noted. Bold values indicate -40°C ≤ T<sub>J</sub> ≤ +125°C.

| Parameter   | Condition  | Min.         | Typ. | Max.         | Units |
|---|--|--------------|------|--------------|-------|
| <b>General</b>  |  |              |      |              |       |
| Operating Input Voltage (V <sub>IN</sub> ) <sup>(5)</sup> |  | <b>3.0</b>   |      | <b>5.5</b>   | V     |
| HSD Voltage Range (V <sub>HSD</sub> )                     |  | <b>3.0</b>   |      | <b>28</b>    | V     |
| Quiescent Supply Current                                  | (V <sub>FB</sub> = 1.5V, output switching but excluding external MOSFET gate current)        |              | 1.4  | <b>3.0</b>   | mA    |
| Standby Supply Current <sup>(6)</sup>                     | V <sub>IN</sub> = V <sub>BST</sub> = 5.5V, V <sub>HSD</sub> = 28, LX = unconnected, EN = GND |              | 0.8  | <b>2</b>     | mA    |
| Under-Voltage Lockout Trip Level                          |  | <b>2.4</b>   | 2.7  | <b>3</b>     | V     |
| UVLO Hysteresis   |  |              | 50   |              | mV    |
| <b>DC-DC Controller</b>                                   |  |              |      |              |       |
| Output-Voltage Adjust Range (V <sub>OUT</sub> )           |  | <b>0.8</b>   |      | <b>5.5</b>   | V     |
| <b>Error Amplifier</b>                                    |  |              |      |              |       |
| FB Regulation Voltage                                     | 0°C ≤ T <sub>J</sub> ≤ 85°C  | <b>-1</b>    |      | <b>1</b>     | %     |
|   | -40°C ≤ T <sub>J</sub> ≤ 125°C   | <b>-2</b>    |      | <b>2</b>     |       |
|   | T <sub>J</sub> = 25°C (MIC2164C)   | -3           |      | 3            |       |
| FB Input Leakage Current                                  |  |              | 5    | <b>500</b>   | nA    |
| Current-Limit Threshold                                   | V <sub>FB</sub> = 0.8V   | <b>103</b>   | 130  | <b>162</b>   | mV    |
|   | V <sub>FB</sub> = 0V   | <b>19</b>    | 48   | <b>77</b>    |       |
|   | V <sub>FB</sub> = 0.8V (MIC2164C)  | <b>95</b>    | 130  | <b>170</b>   |       |
|   | V <sub>FB</sub> = 0V (MIC2164C)  | <b>15</b>    | 48   | <b>80</b>    |       |
| <b>Soft-Start</b>   |  |              |      |              |       |
| Soft-Start Period   |  |              | 6    |              | ms    |
| <b>Oscillator</b>   |  |              |      |              |       |
| Switching Frequency <sup>(8)</sup>                        | MIC2164C   | <b>0.202</b> | 0.27 | <b>0.338</b> | MHz   |
|   | MIC2164  | <b>0.225</b> | 0.3  | <b>0.375</b> |       |
|   | MIC2164-2  | <b>0.45</b>  | 0.6  | <b>0.75</b>  |       |
|   | MIC2164-3  | <b>0.75</b>  | 1    | <b>1.25</b>  |       |

**Electrical Characteristics<sup>(4)</sup> (Continued)**

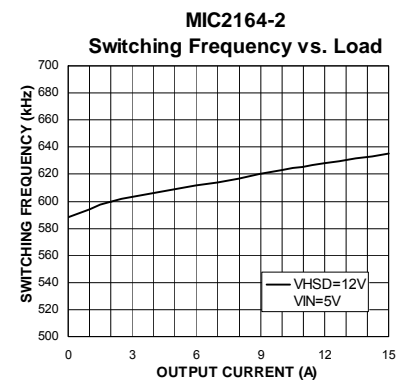
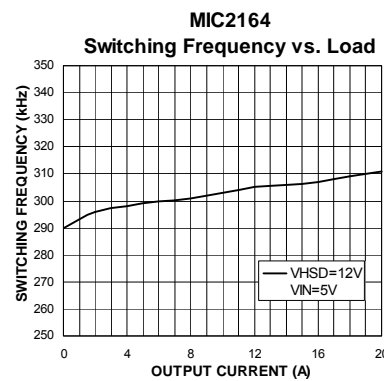
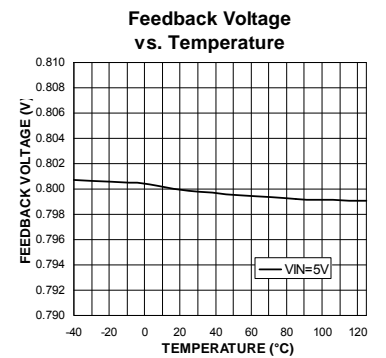
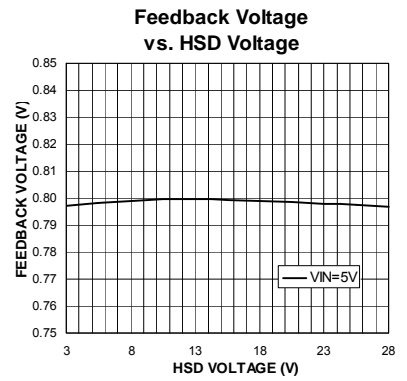
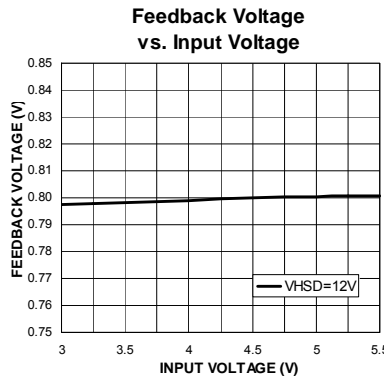
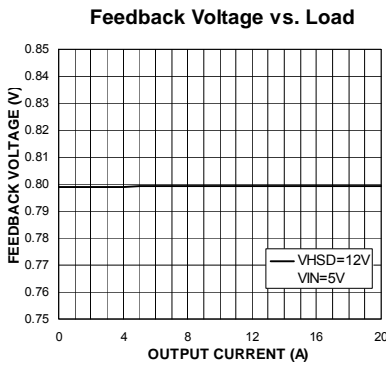
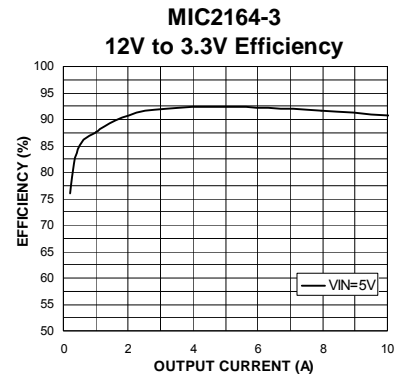
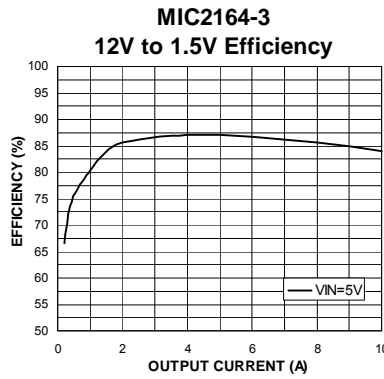
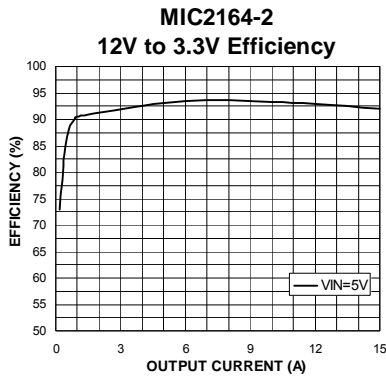
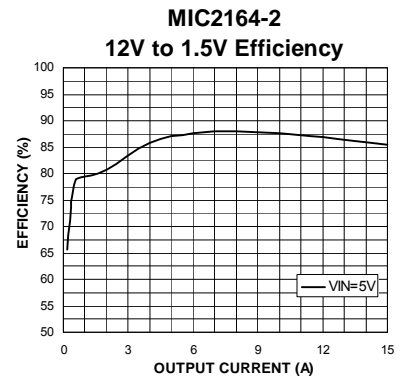
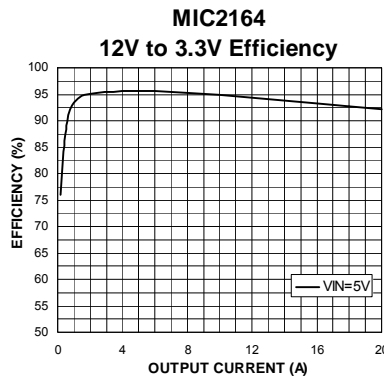
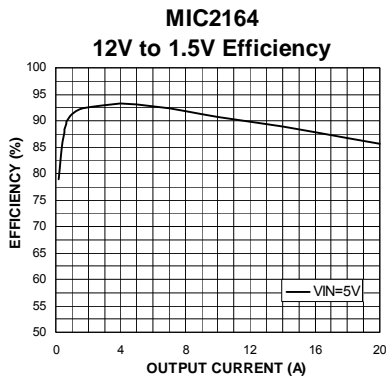
$V_{BST} - V_{LX} = 5V$ ;  $T_A = +25^\circ C$ , unless noted. Bold values indicate  $-40^\circ C \leq T_J \leq +125^\circ C$ .

| Parameter                            | Condition                                      | Min.                                      | Typ. | Max.       | Units      |
|--------------------------------------|--|---|------|------------|------------|
| Maximum Duty Cycle <sup>(9)</sup>    | MIC2164/ MIC2164C                              |   | 87   |            | %          |
|                                      | MIC2164-2                                      |   | 74   |            |            |
|                                      | MIC2164-3                                      |   | 66   |            |            |
| Minimum Duty Cycle                   | Measured at DH, $V_{FB} = 1V$                  |   | 0    |            | %          |
| <b>FET Drives</b>                    |  |   |      |            |            |
| DH, DL Output Low Voltage            | $I_{SINK} = 10mA$                              |   |      | <b>0.1</b> | V          |
| DH, DL Output High Voltage           | $I_{SOURCE} = 10mA$                            | $V_{IN} - 0.1V$<br>or<br>$V_{BST} - 0.1V$ |      |            | V          |
| DH On-Resistance, High State         |  |   | 2.1  | <b>3.3</b> | $\Omega$   |
| DH On-Resistance, Low State          |  |   | 1.8  | <b>3.3</b> | $\Omega$   |
| DL On-Resistance, High State         |  |   | 1.8  | <b>3.3</b> | $\Omega$   |
| DL On-Resistance, Low State          |  |   | 1.2  | <b>2.3</b> | $\Omega$   |
| LX Leakage Current                   | $V_{LX} = 28V, V_{IN} = 5.5V, V_{BST} = 33.5V$ |   |      | <b>50</b>  | $\mu A$    |
| HSD Leakage Current                  | $V_{LX} = 28V, V_{IN} = 5.5V, V_{BST} = 33.5V$ |   |      | <b>20</b>  | $\mu A$    |
| <b>Thermal Protection</b>            |  |   |      |            |            |
| Over-Temperature Shutdown            |  |   | 155  |            | $^\circ C$ |
| Over-Temperature Shutdown Hysteresis |  |   | 10   |            | $^\circ C$ |
| <b>Shutdown Control</b>              |  |   |      |            |            |
| EN Logic Level Low                   | $3V < V_{IN} < 5.5V$                           | <b>0.4</b>                                | 0.8  |            | V          |
| EN Logic Level High                  | $3V < V_{IN} < 5.5V$                           |   | 0.9  | <b>1.2</b> | V          |
| EN Pull-Up Current                   |  |   | 50   |            | $\mu A$    |

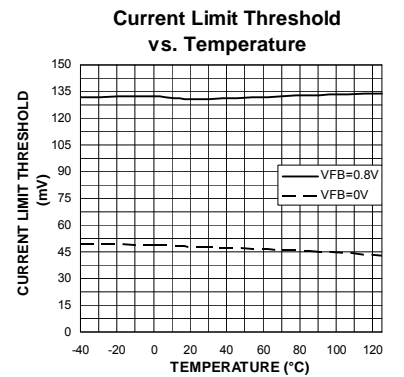
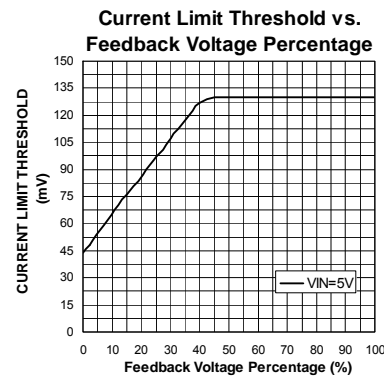
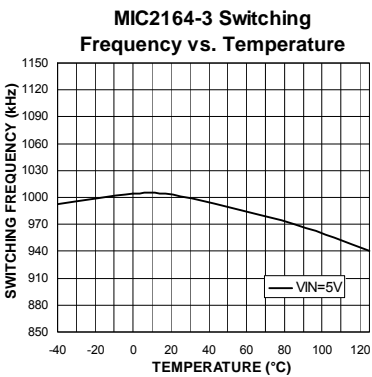
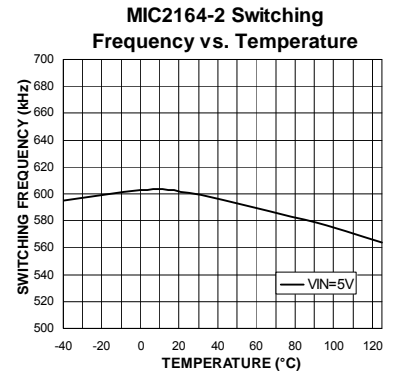
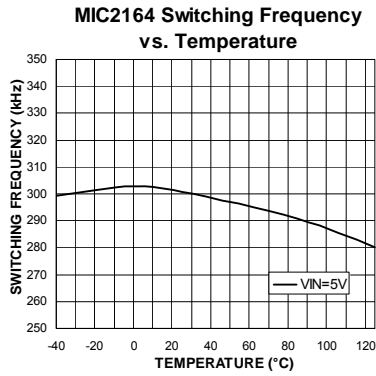
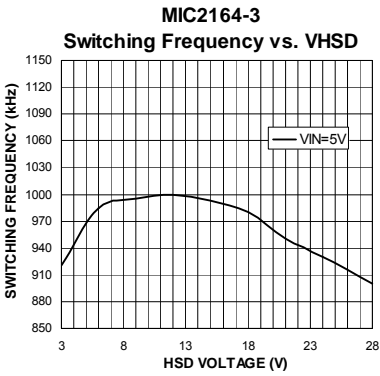
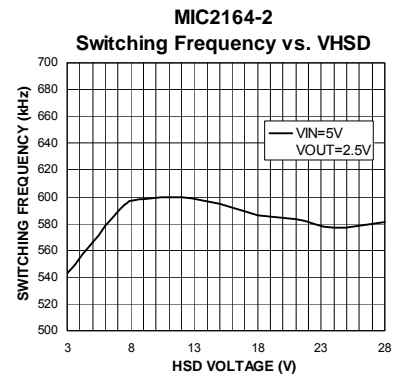
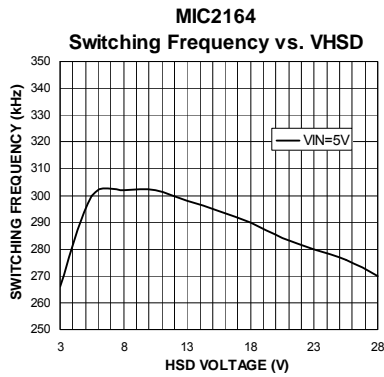
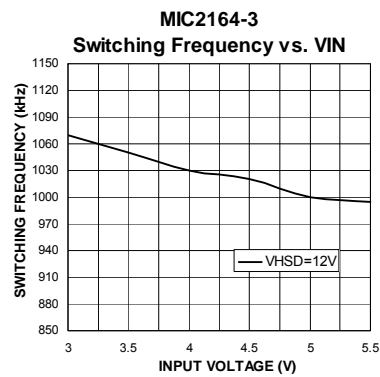
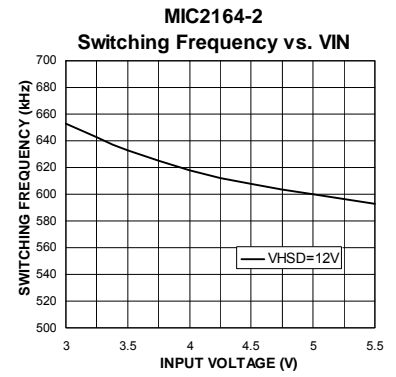
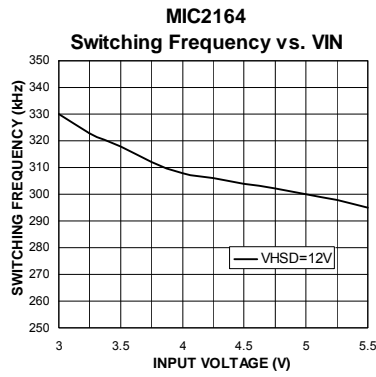
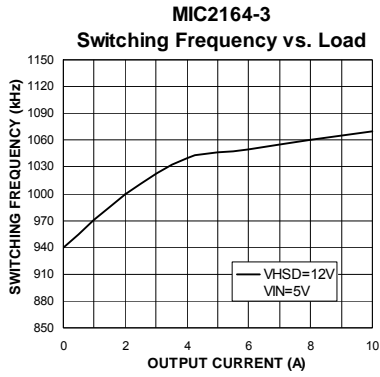
**Note:**

1. Exceeding the absolute maximum rating may damage the device.
2. The device is not guaranteed to function outside its operating rating.
3. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.
4. Specification for packaged product only.
5. The application is fully functional at low IN (supply of the control section) if the external MOSFETs have enough low voltage  $V_{TH}$ .
6. The current will come only from the internal 100k $\Omega$  pull-up resistor sitting on the EN Input and tied to IN.
8. Measured in test mode.
9. Measured at DH. The maximum duty cycle is limited by the fixed mandatory off time  $T_{OFF}$  of typical 363ns.

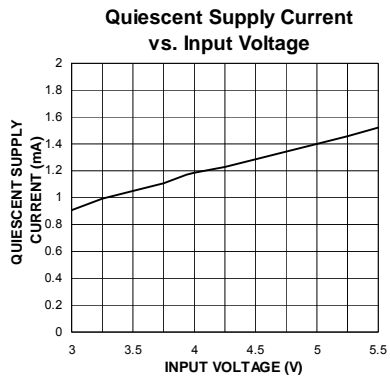
# Typical Characteristics



## Typical Characteristics (Continued)



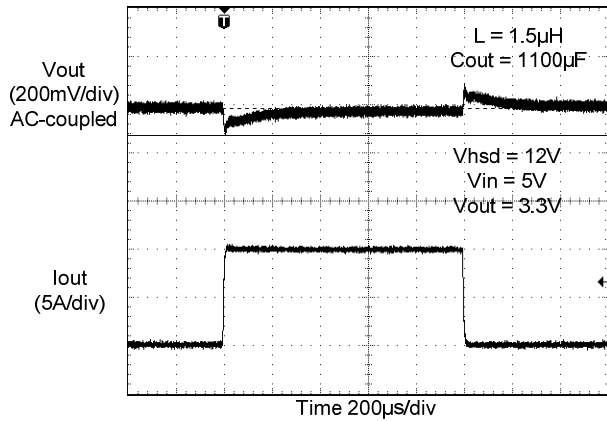
## Typical Characteristics (Continued)



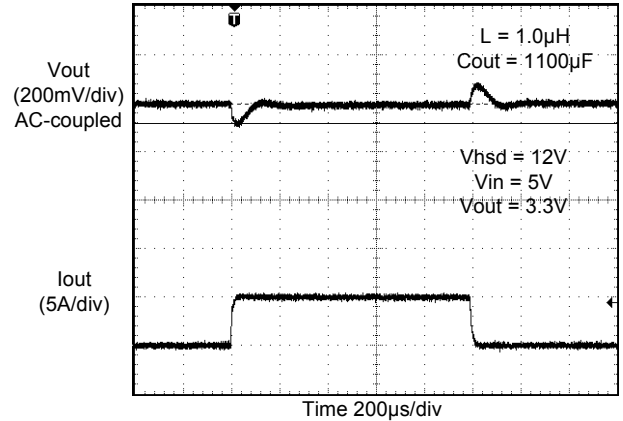


## Functional Characteristics

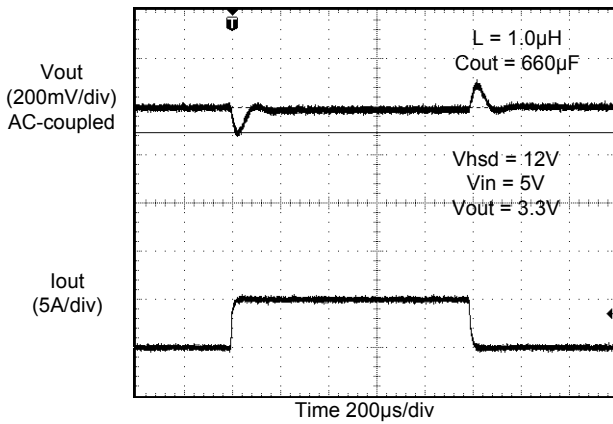
**MIC2164 Load Transient**



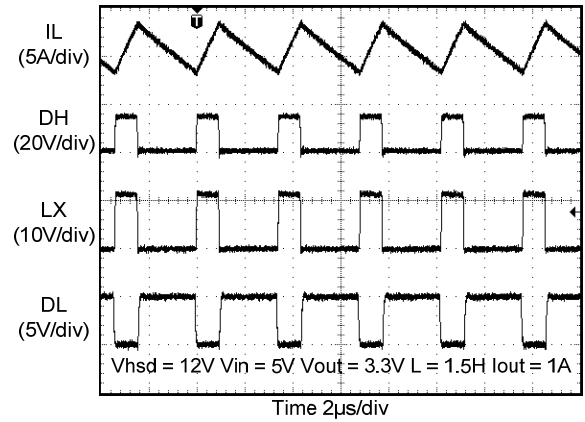
**MIC2164-2 Load Transient**



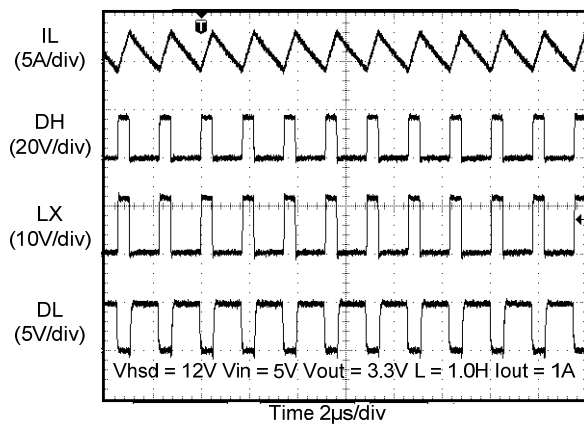
**MIC2164-3 Load Transient**



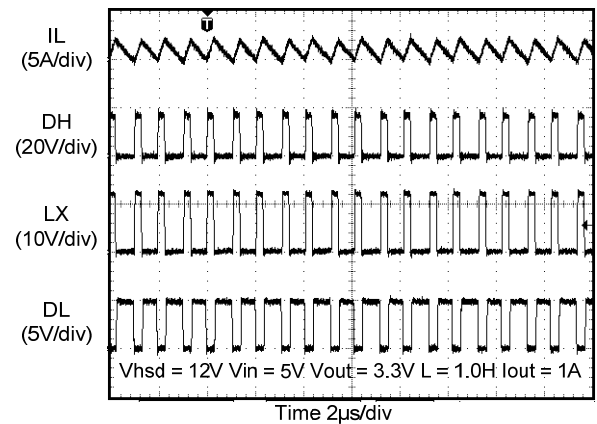
**MIC2164 Switching Waveforms (Light Load)**



**MIC2164-2 Switching Waveforms (Light Load)**

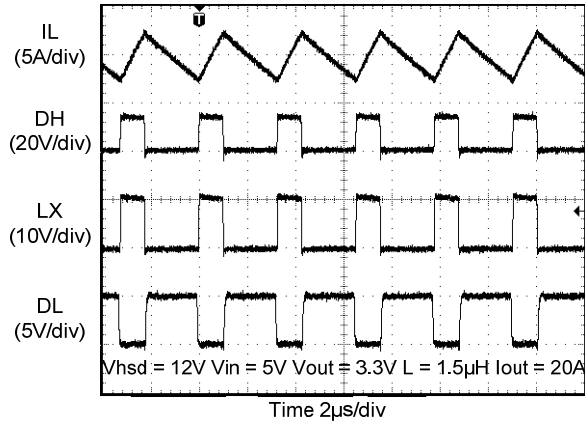


**MIC2164-3 Switching Waveforms (Light Load)**

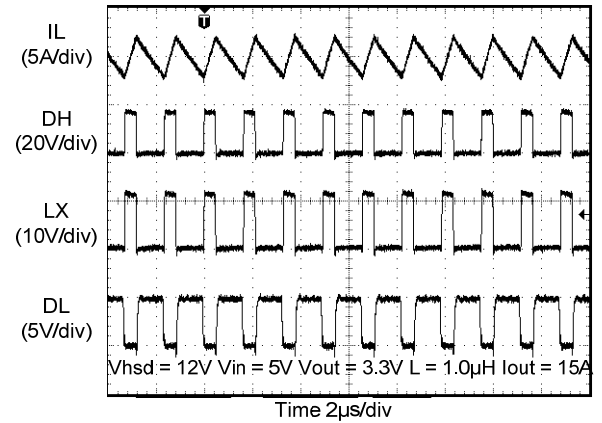


## Functional Characteristics (Continued)

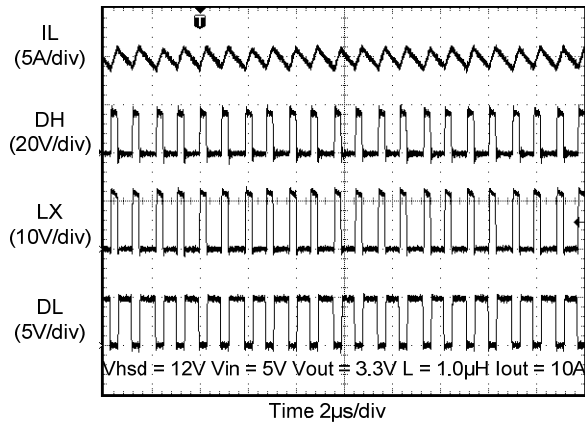
**MIC2164 Switching Waveforms (Heavy Load)**



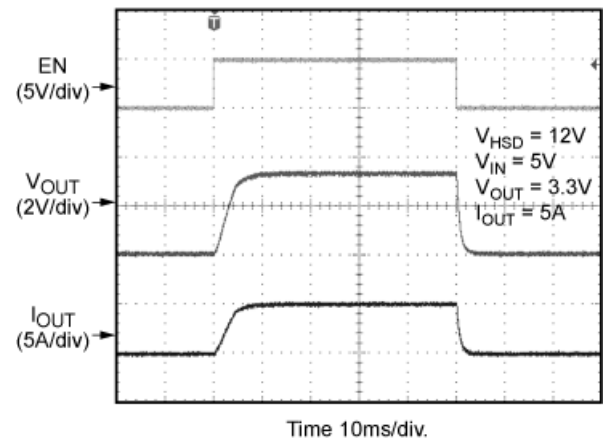
**MIC2164-2 Switching Waveforms (Heavy Load)**



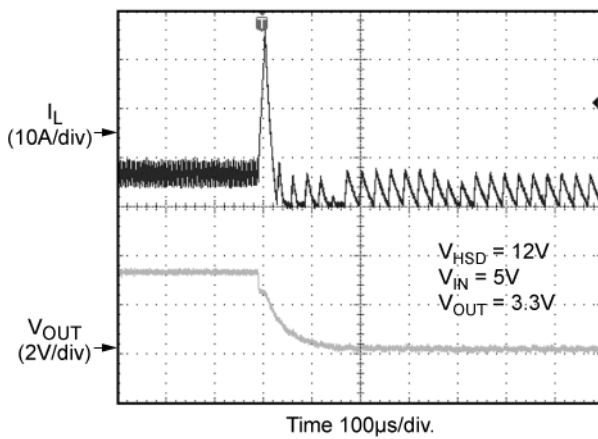
**MIC2164-3 Switching Waveforms (Heavy Load)**



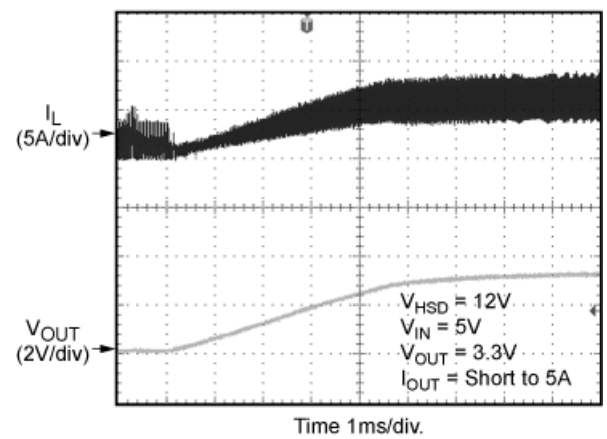
**Power-Up/Power-Down**



**Short Circuit**

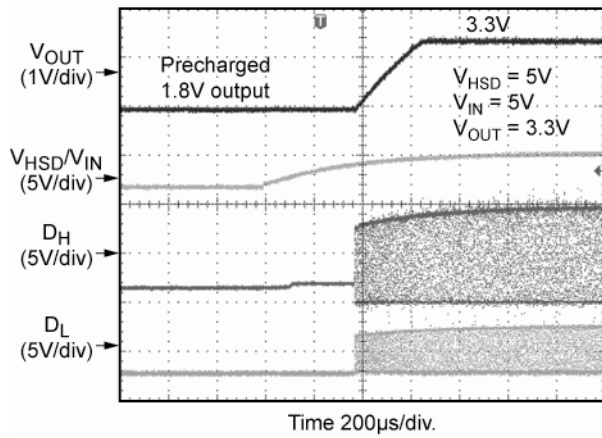


**Short Circuit Recovery**

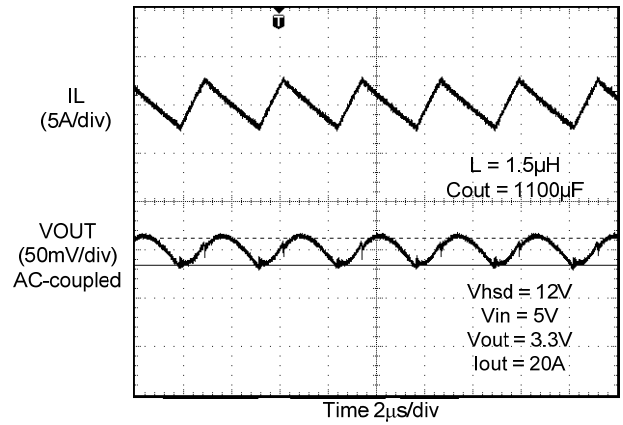


Functional Characteristics (continue)

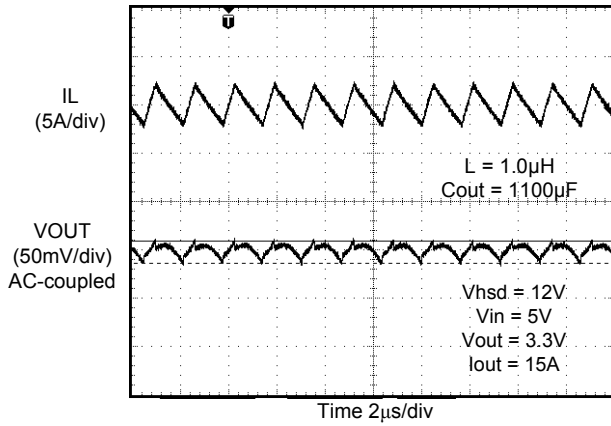
Start-Up with Prebias  $V_{OUT}$



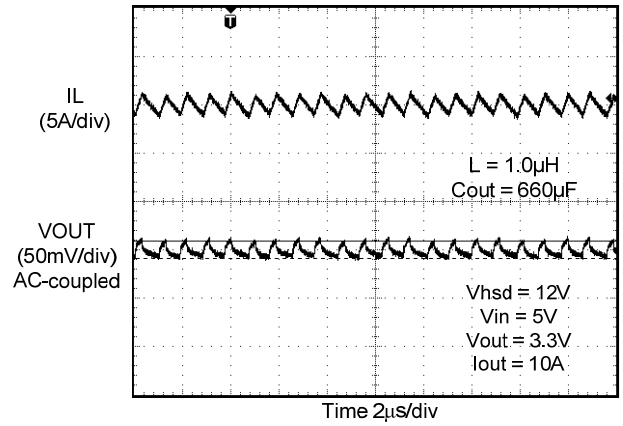
MIC2164 Output Voltage Ripple



MIC2164-2 Output Voltage Ripple



MIC2164-3 Output Voltage Ripple



### Functional Diagram

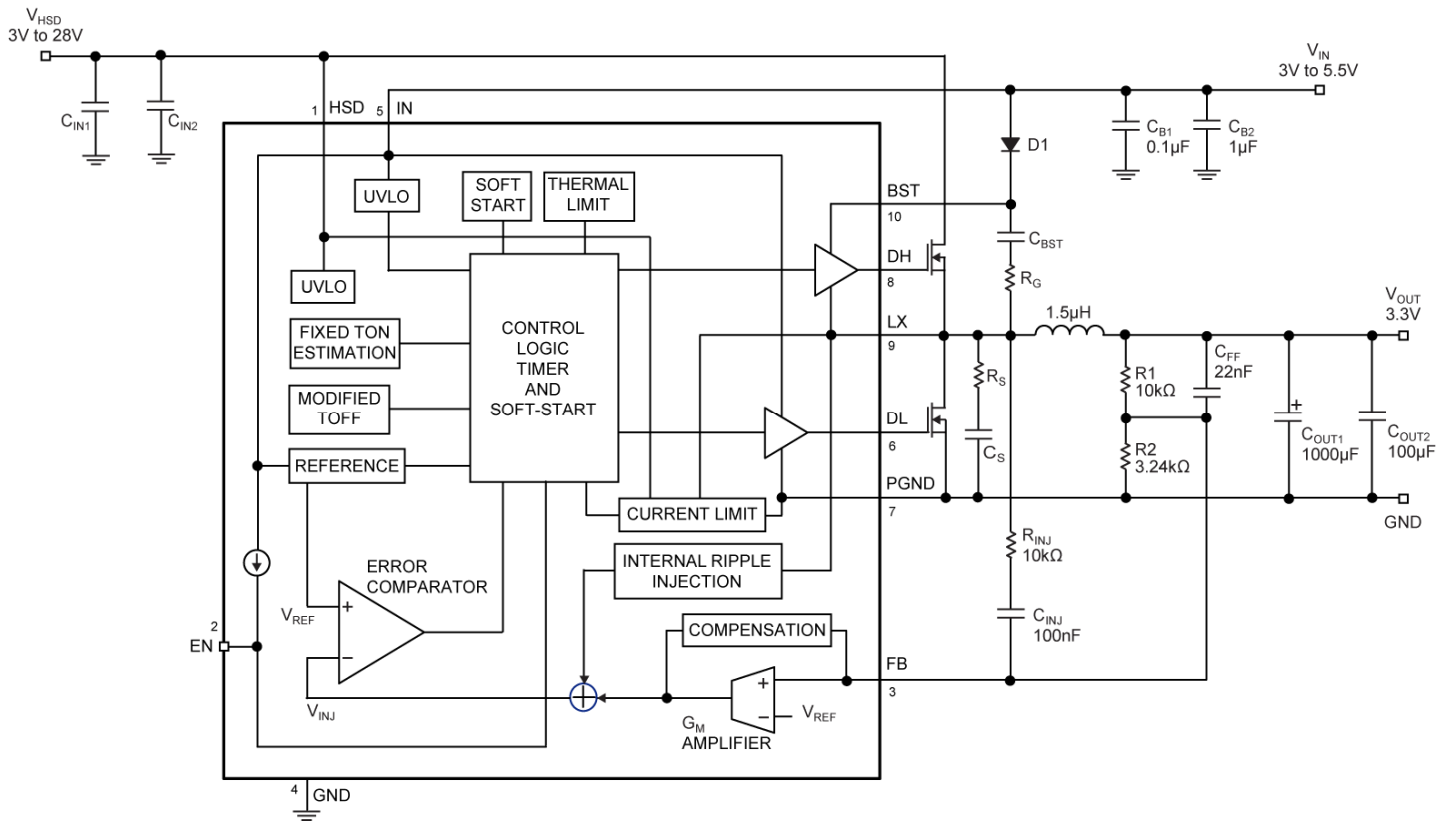


Figure 1. MIC2164/-2/-3 Block Diagram

## Functional Description

The MIC2164/-2/-3 is an adaptive on-time synchronous buck controller family built for low cost and high performance. They are designed for a wide input voltage range from 3V to 28V and for high output power buck converters. An estimated-ON-time method is applied in MIC2164/-2/-3 to obtain a constant switching frequency and to simplify the control compensation. The over-current protection is implemented without the use of an external sense resistor. It includes an internal soft-start function which reduces the power supply input surge current at start-up by controlling the output voltage rise time.

### Theory of Operation

The MIC2164/-2/-3 is a adaptive on-time buck controller family. Figure 1 illustrates the block diagram for the control loop. The output voltage variation will be sensed by the MIC2164/-2/-3 feedback pin FB via the voltage divider R1 and R2, and compared to a 0.8V reference voltage  $V_{REF}$  at the error comparator through a low gain transconductance ( $g_m$ ) amplifier, the amplifier improves the MIC2164/-2/-3 converter output voltage regulation. If the FB voltage decreases and the output of the  $g_m$  amplifier is below 0.8V, The error comparator will trigger the control logic and generate an ON-time period, in which DH pin is logic high and DL pin is logic low. The ON-time period length is predetermined by the "FIXED  $T_{ON}$  ESTIMATION" circuitry:

$$T_{ON(estimated)} = \frac{V_{OUT}}{V_{HSD} \times f_{SW}} \quad (1)$$

where  $V_{OUT}$  is the output voltage,  $V_{HSD}$  is the power stage input voltage, and  $f_{SW}$  is the switching frequency (300kHz for MIC2164, 600kHz for MIC2164-2, and 1MHz for MIC2164-3).

After ON-time period, the MIC2164/-2/-3 goes into the OFF-time period, in which DH pin is logic low and DL pin is logic high. The OFF-time period length is depending on the FB voltage in most cases. When the FB voltage decreases and the output of the  $g_m$  amplifier is below 0.8V, then the ON-time period is trigger and the OFF-time period ends. If the OFF-time period decided by the FB voltage is less than the minimum OFF time  $T_{OFF(min)}$ , which is about 363ns typical, then the MIC2164/-2/-3 control logic will apply the  $T_{OFF(min)}$  instead.  $T_{OFF(min)}$  is required by the BST charging.

The maximum duty cycle is obtained from the 363ns  $T_{OFF(min)}$ :

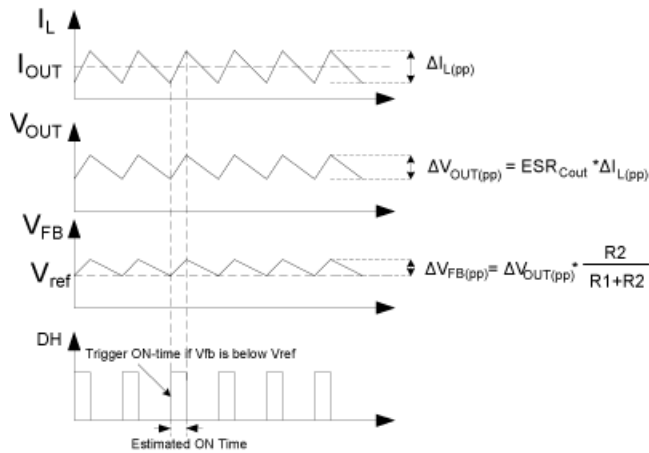
$$D_{max} = \frac{T_S - T_{OFF(min)}}{T_S} = 1 - \frac{363ns}{T_S}$$

where  $T_S = 1/f_{SW}$ .

It is not recommended to use MIC2164/-2/-3 with a OFF time close to  $T_{OFF(min)}$  at the steady state. Also, as  $V_{OUT}$  increases, the internal ripple injection will increase and reduce the line regulation performance. Therefore, the maximum output voltage of the MIC2164/-2/-3 should be limited to 5.5V. If a higher output voltage is required, use the MIC2176 instead. Please refer to "Setting Output Voltage" subsection in "Application Information" for more details.

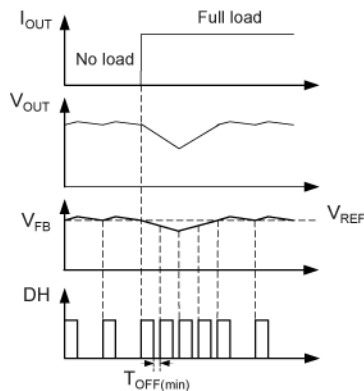
The estimated-ON-time method results in a constant switching frequency in MIC2164/-2/-3. The actual ON time is varied with the different rising and falling time of the external MOSFETs. Therefore, the type of the external MOSFETs, the output load current, and the control circuitry power supply  $V_{IN}$  will modify the actual ON time and the switching frequency. Also, the minimum  $T_{ON}$  results in a lower switching frequency in the high  $V_{HSD}$  and low  $V_{OUT}$  applications, such as 24V to 1.0V MIC2164-3 application. The minimum  $T_{ON}$  measured on the MIC2164 evaluation board is about 138ns. During the load transient, the switching frequency is changed due to the varying OFF time.

To illustrate the control loop, the steady-state scenario and the load transient scenario are analyzed. For easy analysis, the gain of the  $g_m$  amplifier is assumed to be 1. With this assumption, the inverting input of the error comparator is the same as the FB voltage. Figure 2 shows the MIC2164/-2/-3 control loop timing during the steady-state. During the steady-state, the  $g_m$  amplifier senses the FB voltage ripple, which is proportional to the output voltage ripple and the inductor current ripple, to trigger the ON-time period. The ON time is predetermined by the estimation. The ending of OFF time is controlled by the FB voltage. At the valley of the FB voltage ripple, which is below than  $V_{REF}$ , OFF period ends and the next ON-time period is triggered through the control logic circuitry.



**Figure 2. MIC2164/-2/-3 Control Loop Timing**

Figure 3 shows the load transient scenario of the MIC2164/-2/-3 converter. The output voltage drops due to the sudden load increasing, which would cause the FB voltage to be less than  $V_{REF}$ . This will cause the error comparator to trigger ON-time period. At the end of the ON-time period, a minimum OFF time  $T_{OFF(min)}$  is generated to charge BST since the FB voltage is still below the  $V_{REF}$ . Then, the next ON-time period is triggered due to the low FB voltage. Therefore, the switching frequency changes during the load transient. With the varying duty cycle and switching frequency, the output recovery time is fast and the output voltage deviation is small in MIC2164/-2/-3 converter.



**Figure 3. MIC2164/-2/-3 Load-Transient Response**

Unlike the current-mode control, MIC2164/-2/-3 uses the output voltage ripple, which is proportional to the inductor current ripple if the ESR of the output capacitor is large enough, to trigger an ON-time period. The predetermined ON time makes MIC2164/-2/-3 control loop has the advantage as the adaptive on-time mode control. Therefore, the slope compensation, which is necessary for the current-mode control, is not required in the MIC2164/-2/-3 family.

The MIC2164/-2/-3 family has its own stability concern: the FB voltage ripple should be in phase with the inductor current ripple and large enough to be sensed by the  $g_m$  amplifier and the error comparator. The recommended minimum FB voltage ripple is 20mV. If a low ESR output capacitor is selected, then the FB voltage ripple may be too small to be sensed by the  $g_m$  amplifier and the error comparator. Also, the output voltage ripple and the FB voltage ripple are not in phase with the inductor current ripple if the ESR of the output capacitor is very low. Therefore, the ripple injection is required for a low ESR output capacitor. Please refer to “Ripple Injection” subsection in “Application Information” for more details about the ripple injection.

**Soft-Start**

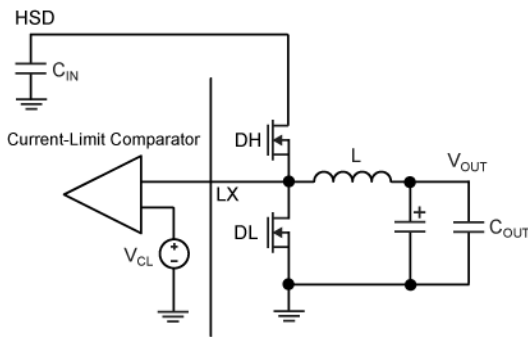
Soft-start reduces the power supply input surge current at startup by controlling the output voltage rise time. The input surge appears while the output capacitor is charged up. A slower output rise time will draw a lower input surge current.

MIC2164/-2/-3 implements an internal digital soft-start by making the 0.8V reference voltage  $V_{REF}$  ramp from 0 to 100% in about 6ms with a 9.7mV step. Therefore, the output voltage is controlled to increase slowly by a staircase  $V_{REF}$  ramp. Once the soft-start ends, the related circuitry is disabled to reduce the current consumption.  $V_{IN}$  should be powered up no earlier than  $V_{HSD}$  to make the soft-start function behavior correctly.

**Current Limit**

The MIC2164/-2/-3 uses the  $R_{DS(ON)}$  of the low-side power MOSFET to sense over-current conditions. The lower-side MOSFET is used because it displays much lower parasitic oscillations during switching than the high-side MOSFET. Using the low-side MOSFET  $R_{DS(ON)}$  as a current sense is an excellent method for circuit protection. This method will avoid adding cost, board space and power losses taken by discrete current sense resistors.

In each switching cycle of the MIC2164/-2/-3 converter, the inductor current is sensed by monitoring the low-side MOSFET in the OFF period. The sensed voltage is compared with a current-limit threshold voltage  $V_{CL}$  after a blanking time of 150ns. If the sensed voltage is over  $V_{CL}$ , which is 130mV typical at 0.8V feedback voltage, the MIC2164/-2/-3 turns off the high-side MOSFET and a soft-start sequence is triggered. This mode of operation is called the “hiccup mode” and its purpose is to protect the down stream load in case of a hard short. The current limit threshold  $V_{CL}$  has a fold back characteristics related to the FB voltage. Please refer to the “Typical Characteristics” for the curve of  $V_{CL}$  vs. FB voltage. The circuit in Figure 4 illustrates the MIC2164/-2/-3 current limiting circuit.



**Figure 4. MIC2164/-2/-3 Current Limiting Circuit**

Using the typical  $V_{CL}$  value of 130mV, the current limit value is roughly estimated as:

$$I_{CL} \approx \frac{130\text{mV}}{R_{DS(ON)}}$$

For designs where the current ripple is significant compared to the load current  $I_{OUT}$ , or for low duty cycle operation, calculating the current limit  $I_{CL}$  should take into account that one is sensing the peak inductor current and that there is a blanking delay of approximately 150ns.

$$I_{CL} = \frac{130\text{mV}}{R_{DS(ON)}} + \frac{V_{OUT} \cdot T_{DLY}}{L} - \frac{\Delta I_{L(pp)}}{2} \quad (2)$$

$$\Delta I_{L(pp)} = \frac{V_{OUT} \cdot (1-D)}{f_{SW} \cdot L} \quad (3)$$

where

$V_{OUT}$  = The output voltage

$T_{DLY}$  = Current limit blanking time, 150ns typical

$\Delta I_{L(pp)}$  = Inductor current ripple peak-to-peak value

D = Duty Cycle

$f_{SW}$  = Switching frequency

The MOSFET  $R_{DS(ON)}$  varies 30 to 40% with temperature; therefore, it is recommended to add a 50% margin to  $I_{CL}$  in the above equation to avoid false current limiting due to increased MOSFET junction temperature rise. It is also recommended to connect LX pin directly to the drain of the low-side MOSFET to accurately sense the MOSFETs  $R_{DS(ON)}$ .

### MOSFET Gate Drive

The MIC2164/-2/-3 high-side drive circuit is designed to switch an N-Channel MOSFET. The block diagram of Figure 1 shows a bootstrap circuit, consisting of D1 (a Schottky diode is recommended) and  $C_{BST}$ . This circuit supplies energy to the high-side drive circuit. Capacitor  $C_{BST}$  is charged while the low-side MOSFET is on and the voltage on the LX pin is approximately 0V. When the high-side MOSFET driver is turned on, energy from  $C_{BST}$  is used to turn the MOSFET on. As the high-side MOSFET turns on, the voltage on the LX pin increases to approximately  $V_{HSD}$ . Diode D1 is reversed biased and  $C_{BST}$  floats high while continuing to keep the high-side MOSFET on. The bias current of the high-side driver is less than 10mA so a 0.1 $\mu$ F to 1 $\mu$ F is sufficient to hold the gate voltage with minimal droop for the power stroke (high-side switching) cycle, i.e.  $\Delta BST = 10\text{mA} \times 3.33\mu\text{s} / 0.1\mu\text{F} = 333\text{mV}$  for MIC2164. When the low-side MOSFET is turned back on,  $C_{BST}$  is recharged through D1. A small resistor  $R_G$ , which is in series with  $C_{BST}$ , can slow down the turn-on time of the high-side N-channel MOSFET.

The drive voltage is derived from the supply voltage  $V_{IN}$ . The nominal low-side gate drive voltage is  $V_{IN}$  and the nominal high-side gate drive voltage is approximately  $V_{IN} - V_{DIODE}$ , where  $V_{DIODE}$  is the voltage drop across D1. An approximate 30ns delay between the high-side and low-side driver transitions is used to prevent current from simultaneously flowing unimpeded through both MOSFETs.

## Application Information

### MOSFET Selection

The MIC2164/-2/-3 controller works from power stage input voltages of 3V to 28V and has an external 3V to 5.5V  $V_{IN}$  to provide power to turn the external N-Channel power MOSFETs for the high- and low-side switches. For applications where  $V_{IN} < 5V$ , it is necessary that the power MOSFETs used are sub-logic level and are in full conduction mode for  $V_{GS}$  of 2.5V. For applications when  $V_{IN} > 5V$ ; logic-level MOSFETs, whose operation is specified at  $V_{GS} = 4.5V$  must be used.

There are different criteria for choosing the high-side and low-side MOSFETs. These differences are more significant at lower duty cycles such as 12V to 1.8V conversion. In such an application, the high-side MOSFET is required to switch as quickly as possible to minimize transition losses, whereas the low-side MOSFET can switch slower, but must handle larger RMS currents. When the duty cycle approaches 50%, the current carrying capability of the high-side MOSFET starts to become critical.

It is important to note that the on-resistance of a MOSFET increases with increasing temperature. A 75°C rise in junction temperature will increase the channel resistance of the MOSFET by 50% to 75% of the resistance specified at 25°C. This change in resistance must be accounted for when calculating MOSFET power dissipation and in calculating the value of current limit. Total gate charge is the charge required to turn the MOSFET on and off under specified operating conditions ( $V_{DS}$  and  $V_{GS}$ ). The gate charge is supplied by the MIC2164/-2/-3 gate-drive circuit. At 300kHz switching frequency and above, the gate charge can be a significant source of power dissipation in the MIC2164/-2/-3. At low output load, this power dissipation is noticeable as a reduction in efficiency. The average current required to drive the high-side MOSFET is:

$$I_{G[\text{high-side}]}(\text{avg}) = Q_G \times f_{\text{SW}} \quad (4)$$

where:

$I_{G[\text{high-side}]}(\text{avg})$  = Average high-side MOSFET gate current

$Q_G$  = Total gate charge for the high-side MOSFET taken from the manufacturer's data sheet for  $V_{GS} = V_{IN}$ .

$f_{\text{SW}}$  = Switching Frequency

The low-side MOSFET is turned on and off at  $V_{DS} = 0$  because an internal body diode or external freewheeling diode is conducting during this time. The switching loss for the low-side MOSFET is usually negligible. Also, the gate-drive current for the low-side MOSFET is more accurately calculated using  $C_{ISS}$  at  $V_{DS} = 0$  instead of gate charge.

For the low-side MOSFET:

$$I_{G[\text{low-side}]}(\text{avg}) = C_{ISS} \times V_{GS} \times f_{\text{SW}} \quad (5)$$

Since the current from the gate drive comes from the  $V_{IN}$ , the power dissipated in the MIC2164/-2/-3 due to gate drive is:

$$P_{\text{GATEDRIVE}} = V_{IN} \cdot (I_{G[\text{high-side}]}(\text{avg}) + I_{G[\text{low-side}]}(\text{avg})) \quad (6)$$

A convenient figure of merit for switching MOSFETs is the on resistance times the total gate charge  $R_{DS(\text{ON})} \times Q_G$ . Lower numbers translate into higher efficiency. Low gate-charge logic-level MOSFETs are a good choice for use with the MIC2164/-2/-3. Also, the  $R_{DS(\text{ON})}$  of the low-side MOSFET will determine the current limit value. Please refer to "Current Limit" subsection is "Functional Description" for more details.

Parameters that are important to MOSFET switch selection are:

- Voltage rating
- On-resistance
- Total gate charge

The voltage ratings for the high-side and low-side MOSFETs are essentially equal to the power stage input voltage  $V_{HSD}$ . A safety factor of 20% should be added to the  $V_{DS(\text{max})}$  of the MOSFETs to account for voltage spikes due to circuit parasitic elements.

The power dissipated in the MOSFETs is the sum of the conduction losses during the on-time ( $P_{\text{CONDUCTION}}$ ) and the switching losses during the period of time when the MOSFETs turn on and off ( $P_{\text{AC}}$ ).

$$P_{\text{SW}} = P_{\text{CONDUCTION}} + P_{\text{AC}} \quad (7)$$

$$P_{\text{CONDUCTION}} = I_{\text{SW(RMS)}}^2 \cdot R_{DS(\text{ON})} \quad (8)$$

$$P_{\text{AC}} = P_{\text{AC(off)}} + P_{\text{AC(on)}} \quad (9)$$

where:

$R_{DS(\text{ON})}$  = on-resistance of the MOSFET switch

$D$  = Duty Cycle =  $V_{\text{OUT}} / V_{\text{HSD}}$



Making the assumption that the turn-on and turn-off transition times are equal; the transition times can be approximated by:

$$t_T = \frac{C_{ISS} \times V_{IN} + C_{OSS} \times V_{HSD}}{I_G} \quad (10)$$

where:

$C_{ISS}$  and  $C_{OSS}$  are measured at  $V_{DS} = 0$

$I_G$  = gate-drive current

The total high-side MOSFET switching loss is:

$$P_{AC} = (V_{HSD} + V_D) \times I_{PK} \times t_T \times f_{SW} \quad (11)$$

where:

$t_T$  = Switching transition time

$V_D$  = Body diode drop (0.5v)

$f_{SW}$  = Switching Frequency

The high-side MOSFET switching losses increase with the switching frequency and the input voltage  $V_{HSD}$ . The low-side MOSFET switching losses are negligible and can be ignored for these calculations.

### Inductor Selection

Values for inductance, peak, and RMS currents are required to select the output inductor. The input and output voltages and the inductance value determine the peak-to-peak inductor ripple current. Generally, higher inductance values are used with higher input voltages. Larger peak-to-peak ripple currents will increase the power dissipation in the inductor and MOSFETs. Larger output ripple currents will also require more output capacitance to smooth out the larger ripple current. Smaller peak-to-peak ripple currents require a larger inductance value and therefore a larger and more expensive inductor. A good compromise between size, loss and cost is to set the inductor ripple current to be equal to 20% of the maximum output current. The inductance value is calculated by the equation below:

$$L = \frac{V_{OUT} \times (V_{HSD(max)} - V_{OUT})}{V_{HSD(max)} \times f_{SW} \times 20\% \times I_{OUT(max)}} \quad (12)$$

where:

$f_{SW}$  = switching frequency

20% = ratio of AC ripple current to DC output current

$V_{HSD(max)}$  = maximum power stage input voltage

The peak-to-peak inductor current ripple is:

$$\Delta I_{L(PP)} = \frac{V_{OUT} \times (V_{HSD(max)} - V_{OUT})}{V_{HSD(max)} \times f_{SW} \times L} \quad (13)$$

The peak inductor current is equal to the average output current plus one half of the peak-to-peak inductor current ripple.

$$I_{L(PK)} = I_{OUT(max)} + 0.5 \times \Delta I_{L(PP)} \quad (14)$$

The RMS inductor current is used to calculate the  $I^2R$  losses in the inductor.

$$I_{L(RMS)} = \sqrt{I_{OUT(max)}^2 + \frac{\Delta I_{L(PP)}^2}{12}} \quad (15)$$

Maximizing efficiency requires both the proper selection of core material and the minimizing of the winding resistance. The high frequency operation of the MIC2164/-2/-3 requires the use of ferrite materials for all but the most cost sensitive applications.

Lower cost iron powder cores may be used but the increase in core loss will reduce the efficiency of the power supply. This is especially noticeable at low output power. The winding resistance decreases efficiency at the higher output current levels. The winding resistance must be minimized although this usually comes at the expense of a larger inductor. The power dissipated in the inductor is equal to the sum of the core and copper losses. At higher output loads, the core losses are usually insignificant and can be ignored. At lower output currents, the core losses can be a significant contributor. Core loss information is usually available from the magnetics vendor. Copper loss in the inductor is calculated by the equation below:

$$P_{INDUCTORCu} = I_{L(RMS)}^2 \times R_{WINDING} \quad (16)$$

The resistance of the copper wire,  $R_{WINDING}$ , increases with the temperature. The value of the winding resistance used should be at the operating temperature.

$$R_{\text{WINDING}} = R_{\text{WINDING}(20^{\circ}\text{C})} \times (1 + 0.0042 \times (T_{\text{H}} - T_{20^{\circ}\text{C}})) \quad (17)$$

where:

$T_{\text{H}}$  = temperature of wire under full load

$T_{20^{\circ}\text{C}}$  = ambient temperature

$R_{\text{WINDING}(20^{\circ}\text{C})}$  = room temperature winding resistance (usually specified by the manufacturer)

### Output Capacitor Selection

The type of the output capacitor is usually determined by its ESR (equivalent series resistance). Voltage and RMS current capability are two other important factors for selecting the output capacitor. Recommended capacitors are tantalum, low-ESR aluminum electrolytic, OS-CON and POSCAPS. The output capacitor's ESR is usually the main cause of the output ripple. The output capacitor ESR also affects the control loop from a stability point of view. The maximum value of ESR is calculated:

$$\text{ESR}_{\text{C}_{\text{OUT}}} \leq \frac{\Delta V_{\text{OUT}(\text{pp})}}{\Delta I_{\text{L}(\text{PP})}} \quad (18)$$

where:

$\Delta V_{\text{OUT}(\text{pp})}$  = peak-to-peak output voltage ripple

$\Delta I_{\text{L}(\text{PP})}$  = peak-to-peak inductor current ripple

The total output ripple is a combination of the ESR and output capacitance. The total ripple is calculated below:

$$\Delta V_{\text{OUT}(\text{pp})} = \sqrt{\left(\frac{\Delta I_{\text{L}(\text{PP})}}{\text{C}_{\text{OUT}} \cdot f_{\text{SW}} \cdot 8}\right)^2 + (\Delta I_{\text{L}(\text{PP})} \cdot \text{ESR}_{\text{C}_{\text{OUT}}})^2} \quad (19)$$

where:

$D$  = duty cycle

$\text{C}_{\text{OUT}}$  = output capacitance value

$f_{\text{SW}}$  = switching frequency

As described in the "Theory of Operation" subsection in "Functional Description", MIC2164/-2/-3 requires at least 20mV peak-to-peak ripple at the FB pin to make the  $g_{\text{m}}$  amplifier and the error comparator to behavior properly. Also, the output voltage ripple should be in phase with the inductor current. Therefore, the output voltage ripple caused by the output capacitor  $\text{C}_{\text{OUT}}$  should be much smaller than the ripple caused by the output capacitor ESR. If low ESR capacitors are selected as the output capacitors, such as ceramic capacitors, a ripple injection method is applied to provide the enough FB voltage ripples. Please refer to the "Ripple Injection" subsection for more details.

The voltage rating of the capacitor should be twice the output voltage for a tantalum and 20% greater for aluminum electrolytic or OS-CON. The output capacitor RMS current is calculated below:

$$I_{\text{C}_{\text{OUT}}(\text{RMS})} = \frac{\Delta I_{\text{L}(\text{PP})}}{\sqrt{12}} \quad (20)$$

The power dissipated in the output capacitor is:

$$P_{\text{DISS}(\text{C}_{\text{OUT}})} = I_{\text{C}_{\text{OUT}}(\text{RMS})}^2 \cdot \text{ESR}_{\text{C}_{\text{OUT}}} \quad (21)$$

### Input Capacitor Selection

The input capacitor for the power stage input  $V_{\text{HSD}}$  should be selected for ripple current rating and voltage rating. Tantalum input capacitors may fail when subjected to high inrush currents, caused by turning the input supply on. A tantalum input capacitor's voltage rating should be at least two times the maximum input voltage to maximize reliability. Aluminum electrolytic, OS-CON, and multilayer polymer film capacitors can handle the higher inrush currents without voltage de-rating. The input voltage ripple will primarily depend upon the input capacitor's ESR. The peak input current is equal to the peak inductor current, so:

$$\Delta V_{\text{IN}} = I_{\text{L}(\text{PK})} \times \text{ESR}_{\text{C}_{\text{IN}}} \quad (22)$$

The input capacitor must be rated for the input current ripple. The RMS value of input capacitor current is determined at the maximum output current. Assuming the peak-to-peak inductor current ripple is low:

$$I_{\text{C}_{\text{IN}}(\text{RMS})} \approx I_{\text{OUT}(\text{max})} \times \sqrt{D \times (1 - D)} \quad (23)$$

The power dissipated in the input capacitor is:

$$P_{\text{DISS}(\text{C}_{\text{IN}})} = I_{\text{C}_{\text{IN}}(\text{RMS})}^2 \times \text{ESR}_{\text{C}_{\text{IN}}} \quad (24)$$

### External Schottky Diode (Optional)

An external freewheeling diode, which is generally not necessary, can be used to keep the inductor current flow continuous while both MOSFETs are turned off. This dead time prevents current from flowing unimpeded through both MOSFETs and is typically 30ns. The diode conducts twice during each switching cycle. Although the average current through this diode is small, the diode must be able to handle the peak current.

$$I_{D(\text{avg})} = I_{\text{OUT}} \cdot 2 \cdot 30\text{ns} \cdot f_{\text{SW}} \quad (25)$$

The reverse voltage requirement of the diode is:

$$V_{\text{DIODE}(\text{rrm})} = V_{\text{HSD}}$$

The power dissipated by the Schottky diode is:

$$P_{\text{DIODE}} = I_{D(\text{avg})} \times V_F \quad (26)$$

where,  $V_F$  = forward voltage at the peak diode current.

The external Schottky diode is not necessary for the circuit operation since the low-side MOSFET contains a parasitic body diode. The external diode will improve efficiency and decrease the high frequency noise. If the MOSFET body diode is then used, it must be rated to handle the peak and average current. The body diode has a relatively slow reverse recovery time and a relatively high forward voltage drop. The power lost in the diode is proportional to the forward voltage drop of the diode. As the high-side MOSFET starts to turn on, the body diode becomes a short circuit for the reverse recovery period, dissipating additional power. The diode recovery and the circuit inductance will cause ringing during the high-side MOSFET turn-on.

An external Schottky diode conducts at a lower forward voltage preventing the body diode in the MOSFET from turning on. The lower forward voltage drop dissipates less power than the body diode. The lack of a reverse recovery mechanism in a Schottky diode causes less ringing and less power loss. Depending upon the circuit components and operating conditions, an external Schottky diode will give a ½ to 1% improvement in efficiency.

### Ripple Injection

The minimum FB voltage ripple requested by the MIC2164/-2/-3  $g_m$  amplifier and error comparator is 20mV (100mV maximum). However, the output voltage ripple is generally designed as 1% to 2% of the output voltage. For a low output voltage, such as 1V output, the output voltage ripple is only 10mV to 20mV, and the FB voltage ripple is less than 20mV. If the FB voltage ripple is so small that the  $g_m$  amplifier and error comparator could not sense it, then the MIC2164/-2/-3 will lose control and the output voltage will not be regulated. In order to have some amount of FB voltage ripple, the ripple injection method is applied for low output voltage ripple applications.

The applications are divided into three situations according to the amount of the FB voltage ripple:

1) Enough ripple at the FB voltage due to the large ESR of the output capacitors.

As shown in Figure 5a, the converter is stable without any adding in this situation. The FB voltage ripple is:

$$\Delta V_{\text{FB}(\text{pp})} = \frac{R_2}{R_1 + R_2} \cdot \text{ESR}_{\text{C}_{\text{OUT}}} \cdot \Delta I_{\text{L}(\text{pp})} \quad (27)$$

where  $\Delta I_{\text{L}(\text{pp})}$  is the peak-to-peak value of the inductor current ripple.

2) Inadequate ripple at the FB voltage due to the small ESR of the output capacitors.

The output voltage ripple is fed into the FB pin through a feedforward capacitor  $C_{\text{ff}}$  in this situation, as shown in Figure 5b. The typical  $C_{\text{ff}}$  value is between 1nF to 100nF. With the feedforward capacitor, the FB voltage ripple is very close to the output voltage ripple:

$$\Delta V_{\text{FB}(\text{pp})} \approx \text{ESR} \cdot \Delta I_{\text{L}(\text{pp})} \quad (28)$$

3) Invisible ripple at the FB voltage is due to the very low ESR of the output capacitors.

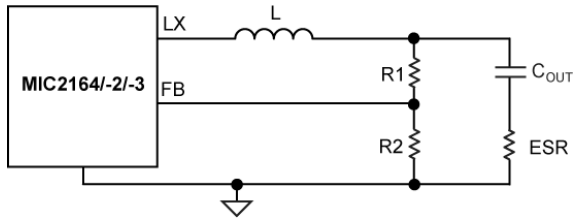


Figure 5a. Enough Ripple at FB

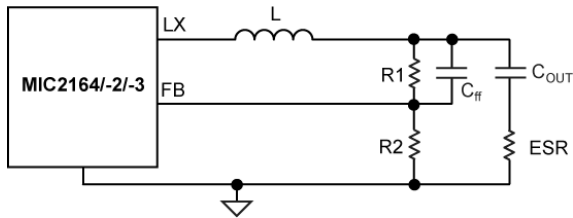


Figure 5b. Inadequate Ripple at FB

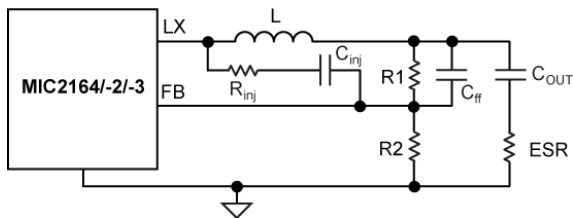


Figure 5c. Invisible Ripple at FB

In this situation, the output voltage ripple is less than 20mV. Therefore, additional ripple is injected into the FB pin from the switching node LX via a resistor Rinj and a capacitor Cinj, as shown in Figure 5c. The injected ripple is:

$$\Delta V_{FB(pp)} = V_{HSD} \times K_{div} \times D \times (1-D) \times \frac{1}{f_{sw} \times \tau} \quad (29)$$

$$K_{div} = \frac{R1//R2}{Rinj + R1//R2} \quad (30)$$

where

V<sub>HSD</sub> = Power stage input voltage at HSD pin

D = Duty Cycle

f<sub>sw</sub> = switching frequency

τ = (R1//R2//Rinj) · Cff

In the formula (29) and (30), it is assumed that the time constant associated with Cff must be much greater than the switching period:

$$\frac{1}{f_{sw} \times \tau} = \frac{T}{\tau} \ll 1$$

If the voltage divider resistors R1 and R2 are in the kΩ range, a Cff of 1nF to 100nF can easily satisfy the large time constant assumption. Also, a 100nF injection capacitor Cinj is used in order to be considered as short for a wide range of the frequencies.

The process of sizing the ripple injection resistor and capacitors is:

**Step 1.** Select Cff to feed all output ripples into the feedback pin and make sure the large time constant assumption is satisfied. Typical choice of Cff is 1nF to 100nF if R1 and R2 are in kΩ range.

**Step 2.** Select Rinj according to the expected feedback voltage ripple. According to the equation (30):

$$K_{div} = \frac{\Delta V_{FB(pp)}}{V_{HSD}} \cdot \frac{f_{sw} \cdot \tau}{D \cdot (1-D)} \quad (31)$$

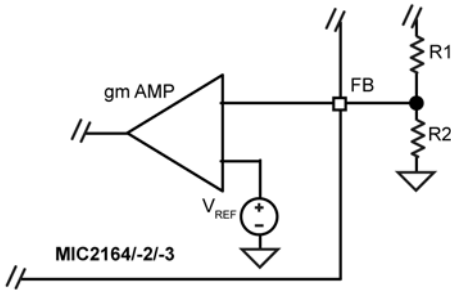
Then the value of Rinj is obtained as:

$$Rinj = (R1//R2) \cdot \left( \frac{1}{K_{div}} - 1 \right) \quad (32)$$

**Step 3.** Select Cinj as 100nF, which could be considered as short for a wide range of the frequencies.

**Setting Output Voltage**

The MIC2164/-2/-3 requires two resistors to set the output voltage, as shown in Figure 6:



**Figure 6. Voltage-Divider Configuration**

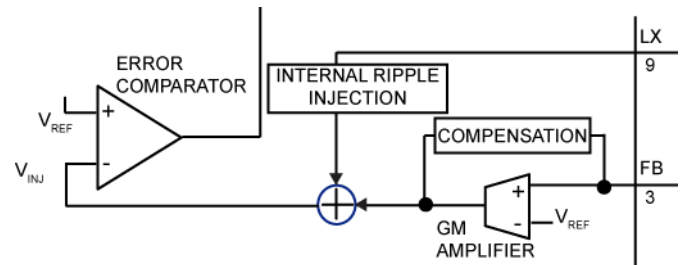
The output voltage is determined by the equation:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right) \tag{33}$$

where  $V_{REF} = 0.8V$ . A typical value of R1 can be between 3kΩ and 10kΩ. If R1 is too large, it may allow noise to be introduced into the voltage feedback loop. If R1 is too small, it will decrease the efficiency of the power supply, especially at light loads. Once R1 is selected, R2 can be calculated using:

$$R2 = \frac{V_{REF} \times R1}{V_{OUT} - V_{REF}} \tag{34}$$

In addition to the external ripple injection added at the FB pin, internal ripple injection is added at the inverting input of the comparator inside the MIC2164/-2/-3, as shown in Figure 7. The inverting input voltage  $V_{INJ}$  is clamped to 1.2V. As  $V_{OUT}$  is increased, the swing of  $V_{INJ}$  will be clamped. The clamped  $V_{INJ}$  reduces the line regulation because it is reflected back as a DC error on the FB terminal. Therefore, the maximum output voltage of the MIC2164/-2/-3 should be limited to 5.5V to avoid this problem. If a higher output voltage is required, use the MIC2176 instead.



**Figure 7. Internal Ripple Injection**

## PCB Layout Guideline

**Warning!!! To minimize EMI and output noise, follow these layout recommendations.**

PCB Layout is critical to achieve reliable, stable and efficient performance. A ground plane is required to control EMI and minimize the inductance in power, signal and return paths.

The following guidelines should be followed to insure proper operation of the MIC2164/-2/-3 converter.

### IC

- Place the IC and MOSFETs close to the point of load (POL).
- Use fat traces to route the input and output power lines.
- Signal and power grounds should be kept separate and connected at only one location.

### Input Capacitor

- Place the HSD input capacitor next.
- Place the HSD input capacitors on the same side of the board and as close to the MOSFETs as possible.
- Keep both the HSD and PGND connections short.
- Place several vias to the ground plane close to the HSD input capacitor ground terminal.
- Use either X7R or X5R dielectric input capacitors. Do not use Y5V or Z5U type capacitors.
- Do not replace the ceramic input capacitor with any other type of capacitor. Any type of capacitor can be placed in parallel with the input capacitor.
- If a Tantalum input capacitor is placed in parallel with the input capacitor, it must be recommended for switching regulator applications and the operating voltage must be derated by 50%.
- In "Hot-Plug" applications, a Tantalum or Electrolytic bypass capacitor must be used to limit the over-voltage spike seen on the input supply with power is suddenly applied.
- An additional Tantalum or Electrolytic bypass input capacitor of 22 $\mu$ F or higher is required at the input power connection.
- The 1 $\mu$ F and 0.1 $\mu$ F capacitors, which connect to the  $V_{IN}$  terminal, must be located right at the IC. The  $V_{IN}$  terminal is very noise sensitive and placement of the

capacitor is very critical. Connections must be made with wide trace.

### Inductor

- Keep the inductor connection to the switch node (LX) short.
- Do not route any digital lines underneath or close to the inductor.
- Keep the switch node (LX) away from the feedback (FB) pin.
- The LX pin should be connected directly to the drain of the low-side MOSFET to accurately sense the voltage across the low-side MOSFET.
- To minimize noise, place a ground plane underneath the inductor.

### Output Capacitor

- Use a wide trace to connect the output capacitor ground terminal to the input capacitor ground terminal.
- Phase margin will change as the output capacitor value and ESR changes. Contact the factory if the output capacitor is different from what is shown in the BOM.
- The feedback trace should be separate from the power trace and connected as close as possible to the output capacitor. Sensing a long high current load trace can degrade the DC load regulation.

### Schottky Diode (Optional)

- Place the Schottky diode on the same side of the board as the MOSFETs and HSD input capacitor.
- The connection from the Schottky diode's Anode to the input capacitors ground terminal must be as short as possible.
- The diode's cathode connection to the switch node (LX) must be kept as short as possible.

### RC Snubber

- Place the RC snubber on the same side of the board and as close to the MOSFETs as possible.

### Evaluation Board Schematics

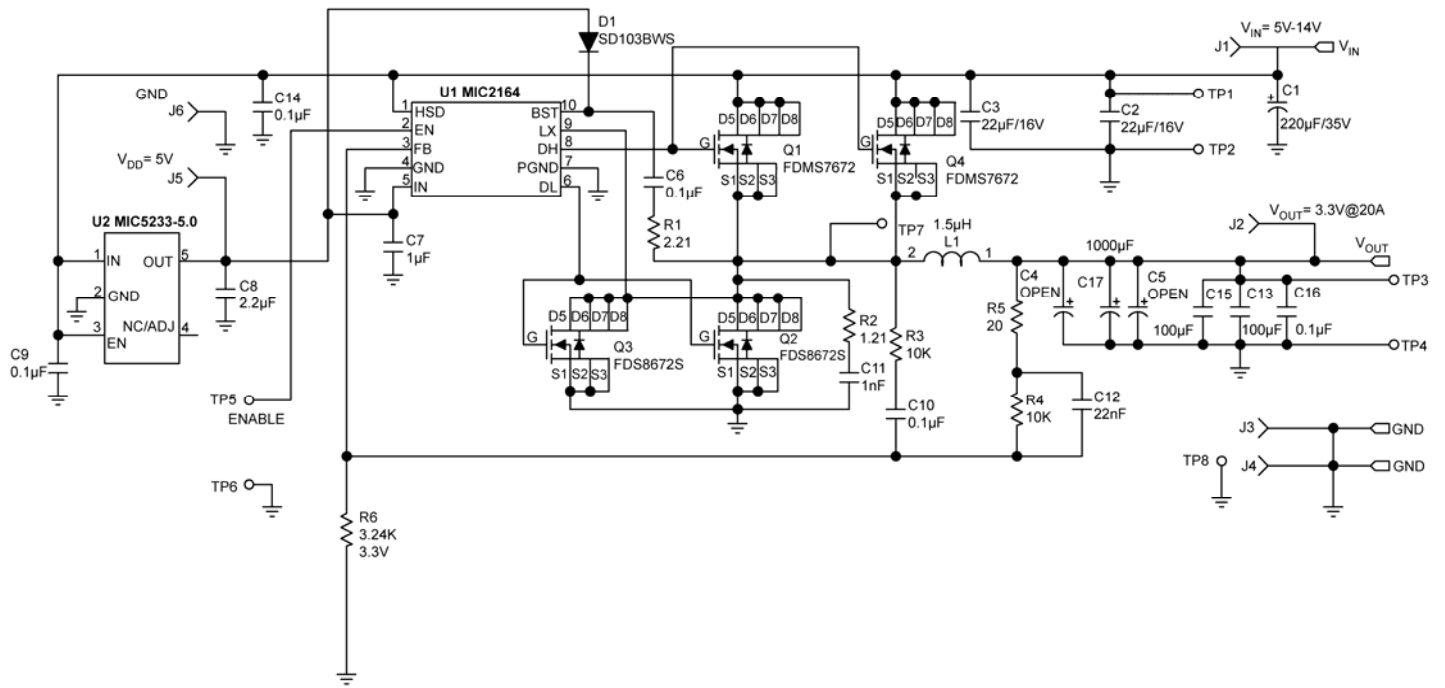


Figure 8. Schematic of MIC2164 20A Evaluation Board

**Bill of Materials**

| Item                  | Part Number        | Manufacturer              | Description   | Qty. |
|-----------------------|--------------------|---------------------------|---|------|
| C1                    | B41125A7227M       | EPCOS <sup>(1)</sup>      | 220µF Aluminum Capacitor, SMD, 35V                    | 1    |
|                       | 222215095001E3     | Vishay <sup>(2)</sup>     |   |      |
| C2,C3                 | 1210YD226KAT2A     | AVX <sup>(3)</sup>        | 22µF Ceramic Capacitor, X5R, Size 1210, 16V           | 2    |
|                       | GRM32ER61C226KE20L | Murata <sup>(4)</sup>     |   |      |
|                       | C3225X5R1C226K     | TDK <sup>(5)</sup>        |   |      |
| C6,C9,C10,<br>C14,C16 | 06035C104KAT2A     | AVX <sup>(3)</sup>        | 0.1µF Ceramic Capacitor, X7R, Size 0603, 50V          | 5    |
|                       | GRM188R71H104KA93D | Murata <sup>(4)</sup>     |   |      |
|                       | C1608X7R1H104K     | TDK <sup>(5)</sup>        |   |      |
| C7                    | 0805ZD105KAT2A     | AVX <sup>(3)</sup>        | 1µF Ceramic Capacitor, X5R, Size 0805, 10V            | 1    |
|                       | GRM219R61A105KC01D | Murata <sup>(4)</sup>     |   |      |
|                       | C2012X5R1A105K     | TDK <sup>(5)</sup>        |   |      |
| C8                    | 0805ZC225MAT2A     | AVX <sup>(3)</sup>        | 2.2µF Ceramic Capacitor, X7R, Size 0805, 10V          | 1    |
|                       | GRM21BR71A225KA01L | Murata <sup>(4)</sup>     |   |      |
|                       | C2012X7R1A225K     | TDK <sup>(5)</sup>        |   |      |
| C11                   | 06035C102KAT2A     | AVX <sup>(3)</sup>        | 1nF Ceramic Capacitor, X7R, Size 0603, 50V            | 1    |
|                       | GRM188R71H102KA01D | Murata <sup>(4)</sup>     |   |      |
|                       | C1608X7R1H102K     | TDK <sup>(5)</sup>        |   |      |
| C12                   | 06035C223KAZ2A     | AVX <sup>(3)</sup>        | 22nF Ceramic Capacitor, X7R, Size 0603, 50V           | 1    |
|                       | GRM188R71H223K     | Murata <sup>(4)</sup>     |   |      |
|                       | C1608X7R1H223K     | TDK <sup>(5)</sup>        |   |      |
| C13,C15               | 12106D107MAT2A     | AVX <sup>(3)</sup>        | 100µF Ceramic Capacitor, X5R, Size 1210, 6.3V         | 2    |
|                       | GRM32ER60J107ME20L | Murata <sup>(4)</sup>     |   |      |
| C17                   | 16ME1000WG         | SANYO <sup>(6)</sup>      | 1000µF Aluminum Capacitor, 16V                        | 1    |
| D1                    | SD103BWS-7         | Diodes Inc <sup>(7)</sup> | Small Signal Schottky Diode                           | 1    |
|                       | SD103BWS           | Vishay <sup>(2)</sup>     |   |      |
| L1                    | CDEP147NP-1R5M     | Sumida <sup>(8)</sup>     | 1.5µH Inductor, 27.2A Saturation Current              | 1    |
| Q1,Q4                 | FDMS7672           | Fairchild <sup>(9)</sup>  | 30V N-Channel MOSFET 6.9mΩ R <sub>DS(ON)</sub> @ 4.5V | 2    |
| Q2,Q3                 | FDS8672S           | Fairchild <sup>(9)</sup>  | 30V N-Channel MOSFET 7mΩ R <sub>DS(ON)</sub> @ 4.5V   | 2    |

**Notes:**

1. EPCOS: [www.epcos.com](http://www.epcos.com).
2. Vishay: [www.vishay.com](http://www.vishay.com).
3. AVX: [www.avx.com](http://www.avx.com).
4. Murata: [www.murata.com](http://www.murata.com).
5. TDK: [www.tdk.com](http://www.tdk.com).
6. Sanyo: [www.sanyo.com](http://www.sanyo.com).
7. Diodes Inc: [www.diodes.com](http://www.diodes.com).
8. Sumida: [www.sumida.com](http://www.sumida.com).
9. Fairchild: [www.fairchildsemi.com](http://www.fairchildsemi.com).



**Bill of Materials (Continued)**

| Item                     | Part Number           | Manufacturer                     | Description                    | Qty.     |
|--------------------------|-----------------------|----------------------------------|--------------------------------|----------|
| R1                       | CRCW06032R21FKEA      | Vishay/Dale <sup>(2)</sup>       | 2.21Ω Resistor, Size 0603, 1%  | 1        |
| R2                       | CRCW06031R21FKEA      | Vishay/Dale <sup>(2)</sup>       | 1.21Ω Resistor, Size 0603, 1%  | 1        |
| R3,R4                    | CRCW060310K0FKEA      | Vishay/Dale <sup>(2)</sup>       | 10kΩ Resistor, Size 0603, 1%   | 2        |
| R5                       | CRCW060320R0FKEA      | Vishay/Dale <sup>(2)</sup>       | 20Ω Resistor, Size 0603, 1%    | 1        |
| R6                       | CRCW06033K24FKEA      | Vishay/Dale <sup>(2)</sup>       | 3.24kΩ Resistor, Size 0603, 1% | 1        |
| <b>U1</b>                | <b>MIC2164YMM</b>     | <b>MICREL INC<sup>(10)</sup></b> | <b>300kHz Buck Controller</b>  | <b>1</b> |
| <b>U2<sup>(11)</sup></b> | <b>MIC5233-5.0YM5</b> | <b>MICREL INC<sup>(10)</sup></b> | <b>LDO</b>                     | <b>1</b> |

**Notes:**

10. Micrel, Inc.: [www.micrel.com](http://www.micrel.com).

11. Optional: Required if 5V supply is not available in the system.

### PCB Layout Recommendations

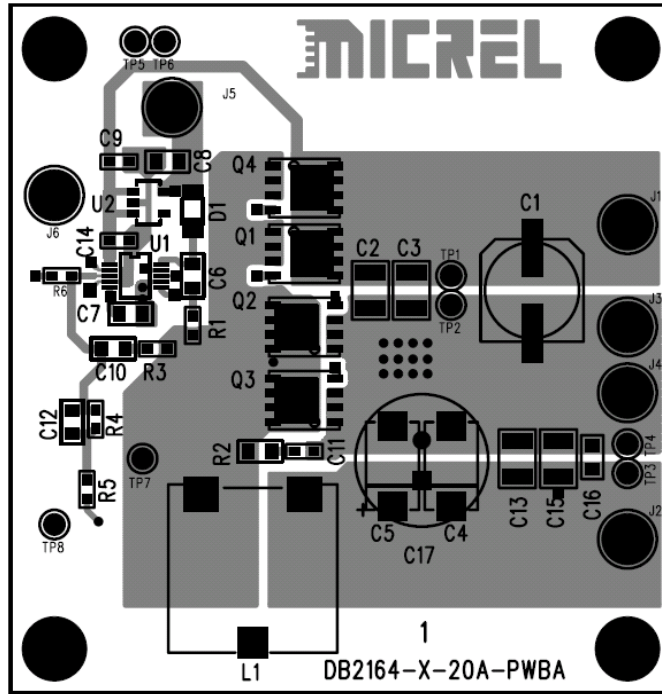


Figure 9. MIC2164 20A Evaluation Board Top Layer

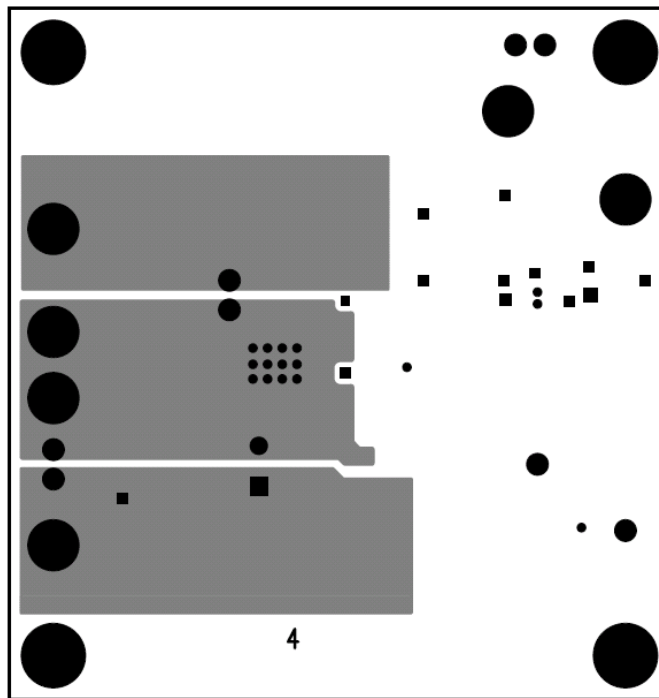


Figure 10. MIC2164 20A Evaluation Board Bottom Layer

### PCB Layout Recommendations (Continued)

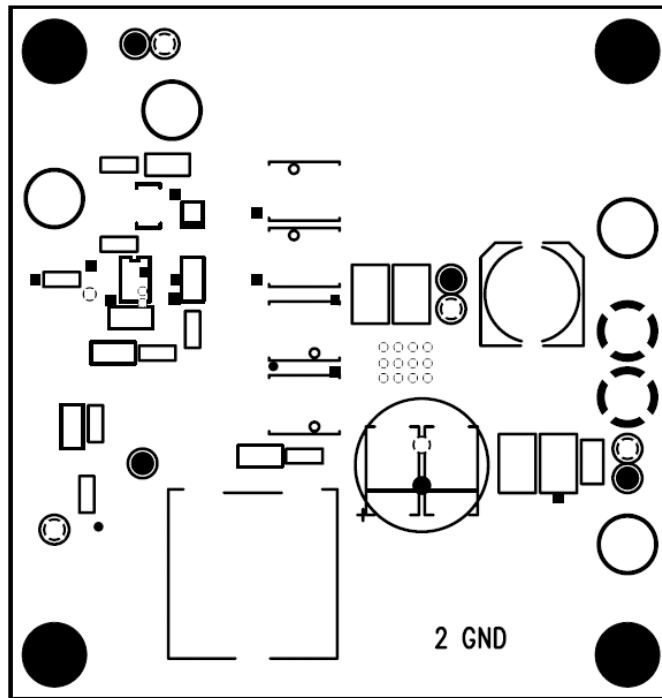


Figure 11. MIC2164 20A Evaluation Board Mid-Layer 1

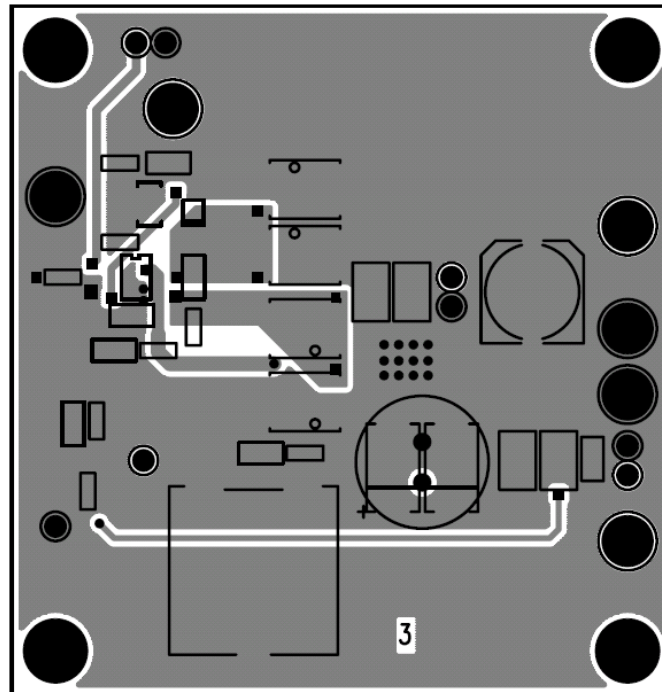


Figure 12. MIC2164 20A Evaluation Board Mid-Layer 2



**Bill of Materials (MIC2164 12V to 3.3V @ 20A)**

| Item             | Part Number       | Manufacturer                | Description   | Qty. |
|------------------|-------------------|-----------------------------|---|------|
| C1, C8, C17, C19 | 06035C104KAT      | AVX <sup>(1)</sup>          | 0.1 $\mu$ F Ceramic Capacitor, X7R, Size 0603, 50V            | 4    |
| C2               | 0805ZD225MAT      | AVX <sup>(1)</sup>          | 2.2 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V            | 1    |
| C3               | 222215095001      | Vishay <sup>(2)</sup>       | 220 $\mu$ F Aluminum Capacitor, SMD, 35V                      | 1    |
| C4, C5, C6       | 1210YD226MAT      | AVX <sup>(1)</sup>          | 22 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 16V             | 3    |
| C9               | 0805ZD105KAT      | AVX <sup>(1)</sup>          | 1 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V              | 1    |
| C10              | 06035C223KAT      | AVX <sup>(1)</sup>          | 22nF Ceramic Capacitor, X7R, Size 0603, 50V                   | 1    |
| C11              | 16ME1000WGL       | Sanyo <sup>(3)</sup>        | 1000 $\mu$ F Aluminum Capacitor, 16V                          | 1    |
| C12              | 12106D107MAT      | AVX <sup>(1)</sup>          | 100 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 6.3V           | 1    |
| C15              | 06035C102KAT      | AVX <sup>(1)</sup>          | 1nF Ceramic Capacitor, X7R, Size 0603, 50V                    | 1    |
| D1               | SD103BWS          | Vishay <sup>(2)</sup>       | Small Signal Schottky Diode                                   | 1    |
| L1               | CDEP147NP-1R5M    | Sumida <sup>(4)</sup>       | 1.5 $\mu$ H Inductor, 27.2A Saturation Current                | 1    |
| Q1, Q4           | FDMS7672          | Fairchild <sup>(5)</sup>    | 30V N-Channel MOSFET 6.9m $\Omega$ R <sub>DS(ON)</sub> @ 4.5V | 2    |
| Q2, Q3           | FDS8672S          | Fairchild <sup>(5)</sup>    | 30V N-Channel MOSFET 7m $\Omega$ R <sub>DS(ON)</sub> @ 4.5V   | 2    |
| R1               | CRCW06032R21FKEY3 | Vishay Dale <sup>(2)</sup>  | 2.21 $\Omega$ Resistor, Size 0603, 1%                         | 1    |
| R5               | CRCW06031R21FKEY3 | Vishay Dale <sup>(2)</sup>  | 1.21 $\Omega$ Resistor, Size 0603, 1%                         | 1    |
| R6, R9           | CRCW06031002FKEY3 | Vishay Dale <sup>(2)</sup>  | 10k Resistor, Size 0603, 1%                                   | 2    |
| R15              | CRCW06033241FKEY3 | Vishay Dale <sup>(2)</sup>  | 3.24k Resistor, Size 0603 1%                                  | 1    |
| U1               | MIC2164YMM        | Micrel, Inc. <sup>(6)</sup> | 300kHz Buck Controller  | 1    |
| U2               | MIC5233-5.0YM5    | Micrel, Inc. <sup>(6)</sup> | LDO   | 1    |

**Notes:**

1. AVX: [www.avx.com](http://www.avx.com).
2. Vishay: [www.vishay.com](http://www.vishay.com).
3. Sanyo: [www.sanyo.com](http://www.sanyo.com).
4. Sumida: [www.sumida.com](http://www.sumida.com).
5. Fairchild: [www.fairchildsemi.com](http://www.fairchildsemi.com).
6. Micrel, Inc: [www.micrel.com](http://www.micrel.com).

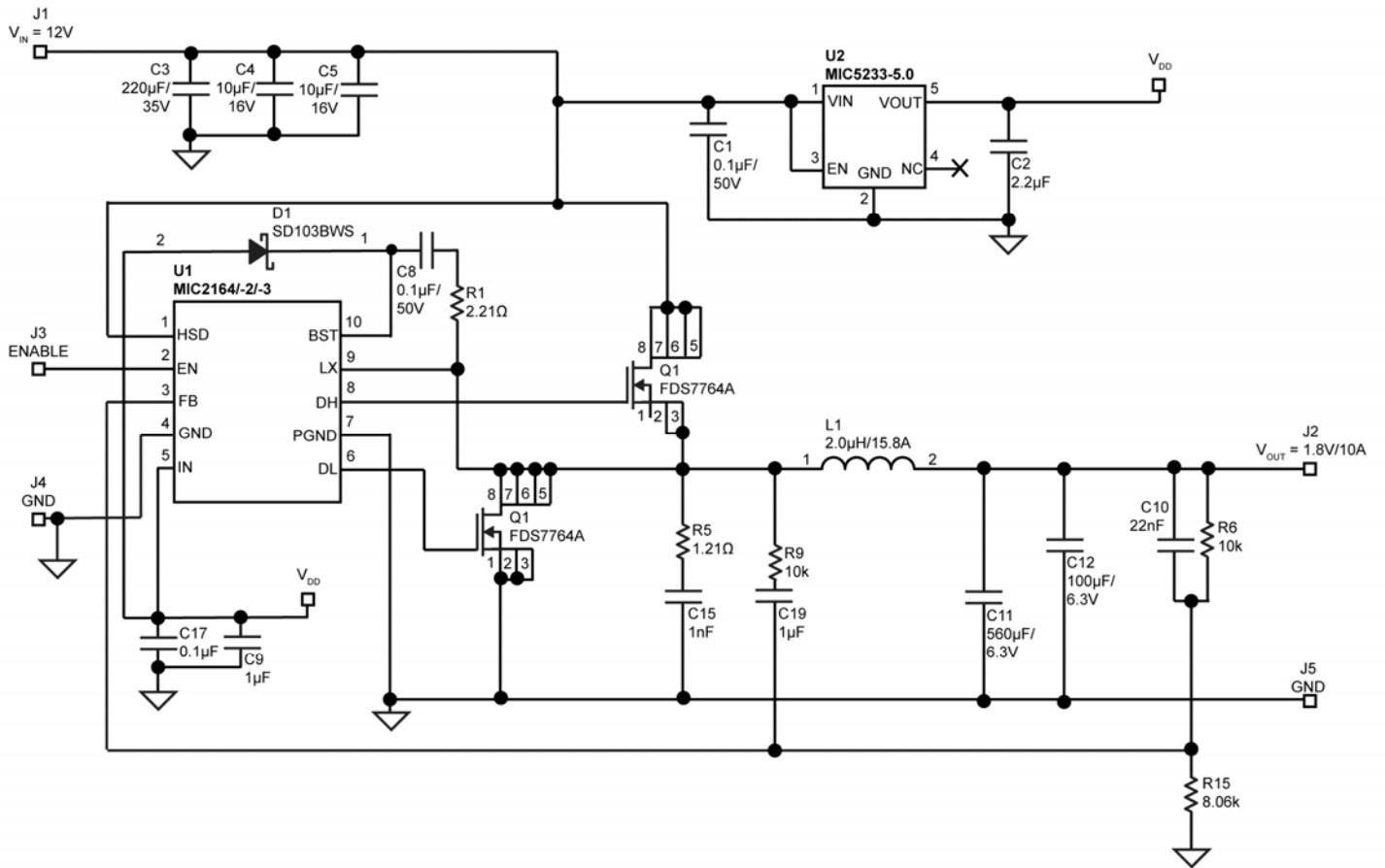


Figure 14. MIC2164 12V to 1.8V @ 10A Buck Converter

**Bill of Materials (MIC2164 12V to 1.8V @ 10A)**

| Item             | Part Number       | Manufacturer                | Description   | Qty. |
|------------------|-------------------|-----------------------------|---|------|
| C1, C8, C17, C19 | 06035C104KAT      | AVX <sup>(1)</sup>          | 0.1 $\mu$ F Ceramic Capacitor, X7R, Size 0603, 50V            | 4    |
| C2               | 0805ZD225MAT      | AVX <sup>(1)</sup>          | 2.2 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V            | 1    |
| C3               | 222215095001      | Vishay <sup>(2)</sup>       | 220 $\mu$ F Aluminum Capacitor, SMD, 35V                      | 1    |
| C4, C5           | 1210YD106MAT      | AVX <sup>(1)</sup>          | 10 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 16V             | 2    |
| C9               | 0805ZD105KAT      | AVX <sup>(1)</sup>          | 1 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V              | 1    |
| C10              | 06035C223KAT      | AVX <sup>(1)</sup>          | 22nF Ceramic Capacitor, X7R, Size 0603, 50V                   | 1    |
| C11              | 6SEPC560MX        | Sanyo <sup>(3)</sup>        | 560 $\mu$ F OSCON Capacitor, 6.3V                             | 1    |
| C12              | 12106D107MAT      | AVX <sup>(1)</sup>          | 100 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 6.3V           | 1    |
| C15              | 06035C102KAT      | AVX <sup>(1)</sup>          | 1nF Ceramic Capacitor, X7R, Size 0603, 50V                    | 1    |
| D1               | SD103BWS          | Vishay <sup>(2)</sup>       | Small Signal Schottky Diode                                   | 1    |
| L1               | CDEP105-2R0MC-32  | Sumida <sup>(4)</sup>       | 2.0 $\mu$ H Inductor, 15.8A Saturation Current                | 1    |
| Q1, Q2           | FDS7764A          | Fairchild <sup>(5)</sup>    | 30V N-Channel MOSFET 7.5m $\Omega$ R <sub>DS(ON)</sub> @ 4.5V | 2    |
| R1               | CRCW06032R21FKEY3 | Vishay Dale <sup>(2)</sup>  | 2.21 $\Omega$ Resistor, Size 0603, 1%                         | 1    |
| R5               | CRCW06031R21FKEY3 | Vishay Dale <sup>(2)</sup>  | 1.21 $\Omega$ Resistor, Size 0603, 1%                         | 1    |
| R6, R9           | CRCW06031002FKEY3 | Vishay Dale <sup>(2)</sup>  | 10k Resistor, Size 0603, 1%                                   | 2    |
| R15              | CRCW06038061FKEY3 | Vishay Dale <sup>(2)</sup>  | 8.06k Resistor, Size 0603, 1%                                 | 1    |
| U1               | MIC2164YMM        | Micrel, Inc. <sup>(6)</sup> | 300kHz Buck Controller  | 1    |
| U2               | MIC5233-5.0YM5    | Micrel, Inc. <sup>(6)</sup> | LDO   | 1    |

**Notes:**

1. AVX: [www.avx.com](http://www.avx.com).
2. Vishay: [www.vishay.com](http://www.vishay.com).
3. Sanyo: [www.sanyo.com](http://www.sanyo.com).
4. Sumida: [www.sumida.com](http://www.sumida.com).
5. Fairchild: [www.fairchildsemi.com](http://www.fairchildsemi.com).
6. Micrel, Inc: [www.micrel.com](http://www.micrel.com).

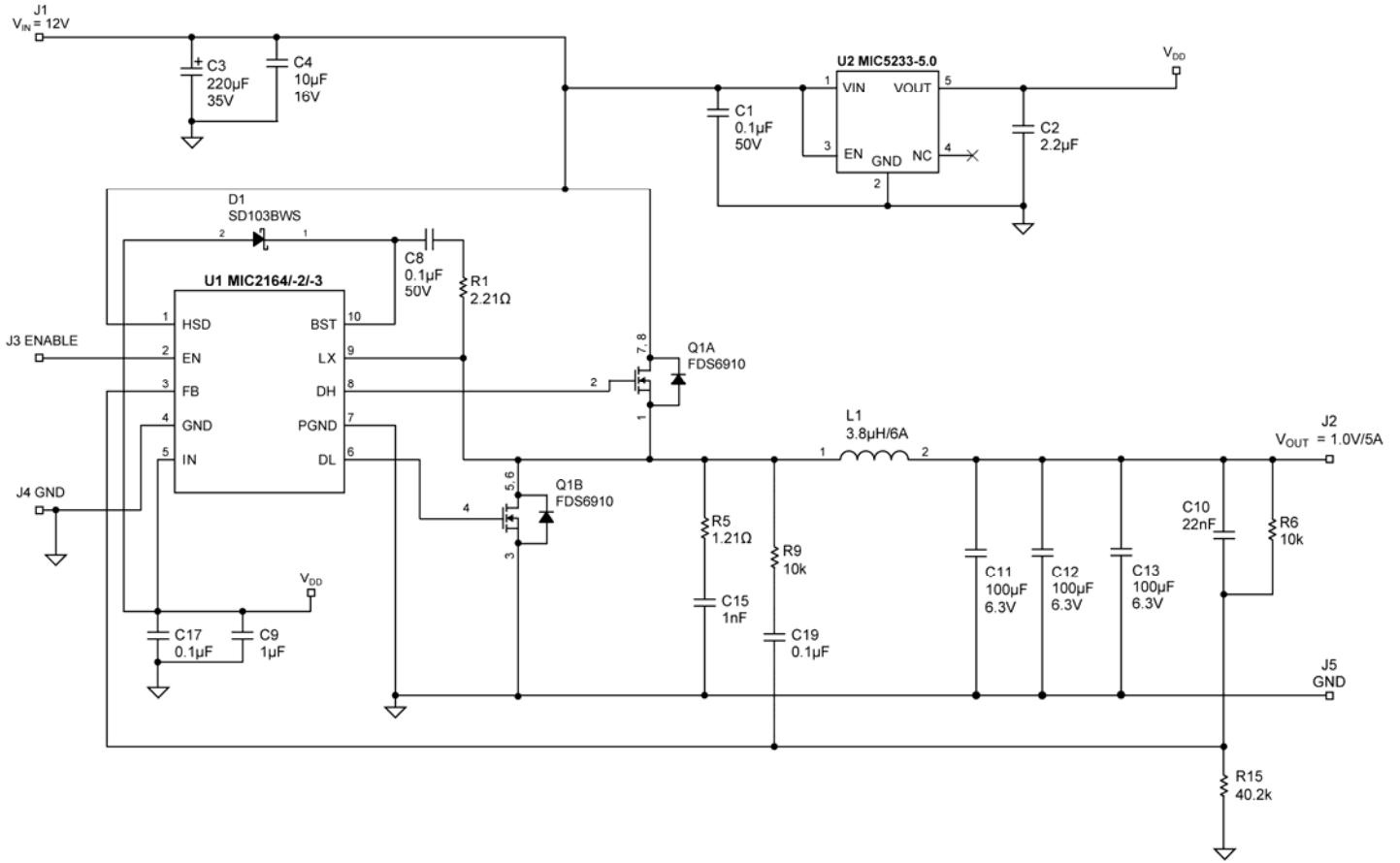


Figure 15. MIC2164 12V to 1.0V @ 5A Buck Converter



**Bill of Materials (MIC2164 12V to 1.0V @ 5A)**

| Item             | Part Number           | Manufacturer                      | Description   | Qty.     |
|------------------|-----------------------|-----------------------------------|---|----------|
| C1, C8, C17, C19 | 06035C104KAT          | AVX <sup>(1)</sup>                | 0.1 $\mu$ F Ceramic Capacitor, X7R, Size 0603, 50V                | 4        |
| C2               | 0805ZD225MAT          | AVX                               | 2.2 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V                | 1        |
| C3               | 222215095001          | Vishay <sup>(2)</sup>             | 220 $\mu$ F Aluminum Capacitor, SMD, 35V                          | 1        |
| C4               | 1210YD106MAT          | AVX                               | 10 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 16V                 | 1        |
| C9               | 0805ZD105KAT          | AVX                               | 1 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V                  | 1        |
| C10              | 06035C223KAT          | AVX                               | 22nF Ceramic Capacitor, X7R, Size 0603, 50V                       | 1        |
| C11, C12, C13    | 12106D107MAT          | AVX                               | 100 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 6.3V               | 3        |
| C15              | 06035C102KAT          | AVX                               | 1nF Ceramic Capacitor, X7R, Size 0603, 50V                        | 1        |
| D1               | SD103BWS              | Vishay                            | Small Signal Schottky Diode                                       | 1        |
| L1               | CDRH104RNP-3R8        | Sumida <sup>(4)</sup>             | 3.8 $\mu$ H Inductor, 6A Saturation Current                       | 1        |
| Q1               | FDS6910               | Fairchild <sup>(5)</sup>          | Dual 30V N-Channel MOSFET 17m $\Omega$ R <sub>DS(ON)</sub> @ 4.5V | 1        |
| R1               | CRCW06032R21FKEY3     | Vishay Dale <sup>(2)</sup>        | 2.21 $\Omega$ Resistor, Size 0603, 1%                             | 1        |
| R5               | CRCW06031R21FKEY3     | Vishay Dale                       | 1.21 $\Omega$ Resistor, Size 0603, 1%                             | 1        |
| R6, R9           | CRCW06031002FKEY3     | Vishay Dale                       | 10k Resistor, Size 0603, 1%                                       | 2        |
| R15              | CRCW06034022FKEY3     | Vishay Dale                       | 40.2k Resistor, Size 0603, 1%                                     | 1        |
| <b>U1</b>        | <b>MIC2164YMM</b>     | <b>Micrel, Inc.<sup>(6)</sup></b> | <b>300kHz Buck Controller</b>                                     | <b>1</b> |
| <b>U2</b>        | <b>MIC5233-5.0YM5</b> | <b>Micrel, Inc.</b>               | <b>LDO</b>  | <b>1</b> |

**Notes:**

1. AVX: [www.avx.com](http://www.avx.com).
2. Vishay: [www.vishay.com](http://www.vishay.com).
3. Sanyo: [www.sanyo.com](http://www.sanyo.com).
4. Sumida: [www.sumida.com](http://www.sumida.com).
5. Fairchild: [www.fairchildsemi.com](http://www.fairchildsemi.com).
6. Micrel, Inc: [www.micrel.com](http://www.micrel.com).

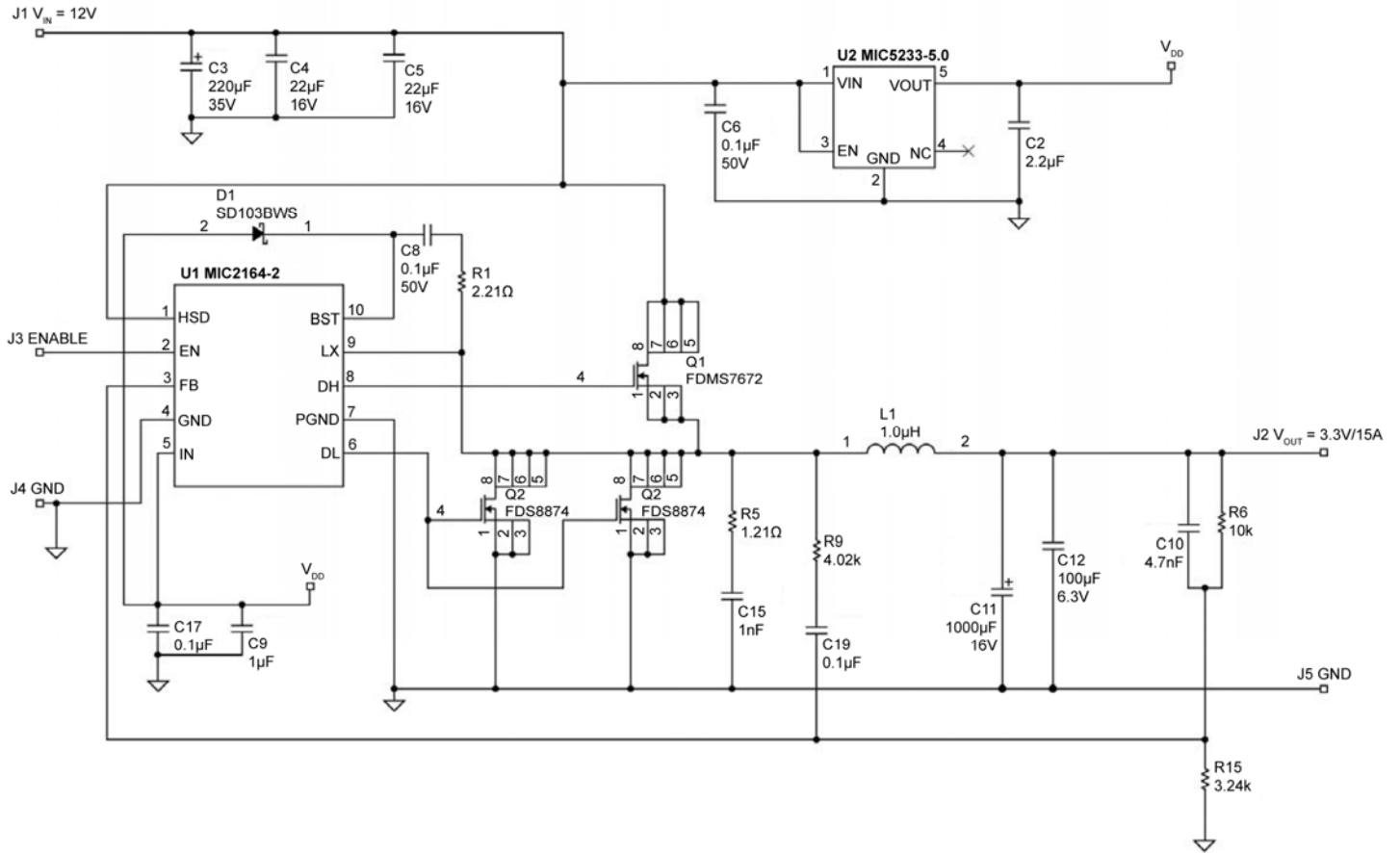


Figure 16. MIC2164-2 12V to 3.3V @ 15A Buck Converter

**Bill of Materials (MIC2164-2 12V to 3.3V @ 15A)**

| Item             | Part Number       | Manufacturer                   | Description   | Qty. |
|------------------|-------------------|--------------------------------|---|------|
| C1, C8, C17, C19 | 06035C104KAT      | AVX <sup>(1)</sup>             | 0.1 $\mu$ F Ceramic Capacitor, X7R, Size 0603, 50V            | 4    |
| C2               | 0805ZD225MAT      | AVX <sup>(1)</sup>             | 2.2 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V            | 1    |
| C3               | 222215095001      | Vishay <sup>(2)</sup>          | 220 $\mu$ F Aluminum Capacitor, SMD, 35V                      | 1    |
| C4, C5           | 1210YD226MAT      | AVX <sup>(1)</sup>             | 22 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 16V             | 2    |
| C9               | 0805ZD105KAT      | AVX <sup>(1)</sup>             | 1 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V              | 1    |
| C10              | 06035C472KAT      | AVX <sup>(1)</sup>             | 4.7nF Ceramic Capacitor, X7R, Size 0603, 50V                  | 1    |
| C11              | 16ME1000WGL       | Sanyo <sup>(3)</sup>           | 1000 $\mu$ F Aluminum Capacitor, 16V                          | 1    |
| C12              | 12106D107MAT      | AVX <sup>(1)</sup>             | 100 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 6.3V           | 1    |
| C15              | 06035C102KAT      | AVX <sup>(1)</sup>             | 1nF Ceramic Capacitor, X7R, Size 0603, 50V                    | 1    |
| D1               | SD103BWS          | Vishay <sup>(2)</sup>          | Small Signal Schottky Diode                                   | 1    |
| L1               | HCP1305-1R0       | Cooper Bussmann <sup>(4)</sup> | 1.0 $\mu$ H Inductor, 29A DC Current                          | 1    |
| Q1               | FDMS7672          | Fairchild <sup>(5)</sup>       | 30V N-Channel MOSFET 6.9m $\Omega$ R <sub>DS(ON)</sub> @ 4.5V | 1    |
| Q2, Q3           | FDS8874           | Fairchild <sup>(5)</sup>       | 30V N-Channel MOSFET 7.0m $\Omega$ R <sub>DS(ON)</sub> @ 4.5V | 2    |
| R1               | CRCW06032R21FKEY3 | Vishay Dale <sup>(2)</sup>     | 2.21 $\Omega$ Resistor, Size 0603, 1%                         | 1    |
| R5               | CRCW06031R21FKEY3 | Vishay Dale <sup>(2)</sup>     | 1.21 $\Omega$ Resistor, Size 0603, 1%                         | 1    |
| R6               | CRCW06031002FKEY3 | Vishay Dale <sup>(2)</sup>     | 10k Resistor, Size 0603, 1%                                   | 1    |
| R9               | CRCW06034021FKEY3 | Vishay Dale <sup>(2)</sup>     | 4.02k Resistor, Size 0603, 1%                                 | 1    |
| R15              | CRCW06033241FKEY3 | Vishay Dale <sup>(2)</sup>     | 3.24k Resistor, Size 0603 1%                                  | 1    |
| U1               | MIC2164-2YMM      | Micrel, Inc. <sup>(6)</sup>    | 600kHz Buck Controller  | 1    |
| U2               | MIC5233-5.0YM5    | Micrel, Inc. <sup>(6)</sup>    | LDO   | 1    |

**Notes:**

1. AVX: [www.avx.com](http://www.avx.com).
2. Vishay: [www.vishay.com](http://www.vishay.com).
3. Sanyo: [www.sanyo.com](http://www.sanyo.com).
4. Sumida: [www.sumida.com](http://www.sumida.com).
5. Fairchild: [www.fairchildsemi.com](http://www.fairchildsemi.com).
6. Micrel, Inc: [www.micrel.com](http://www.micrel.com).

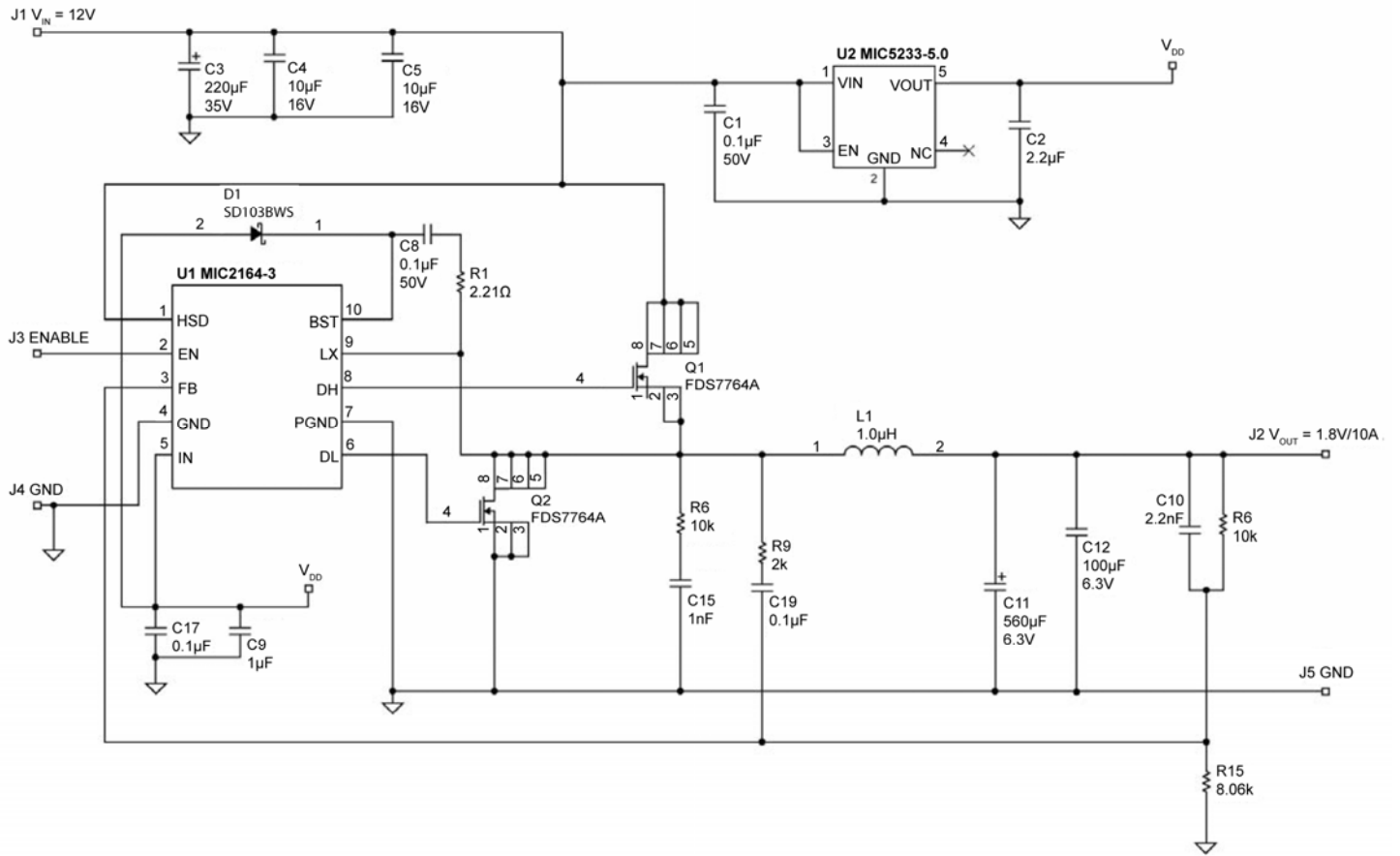


Figure 17. MIC2164-3 12V to 1.8V @ 10A Buck Converter

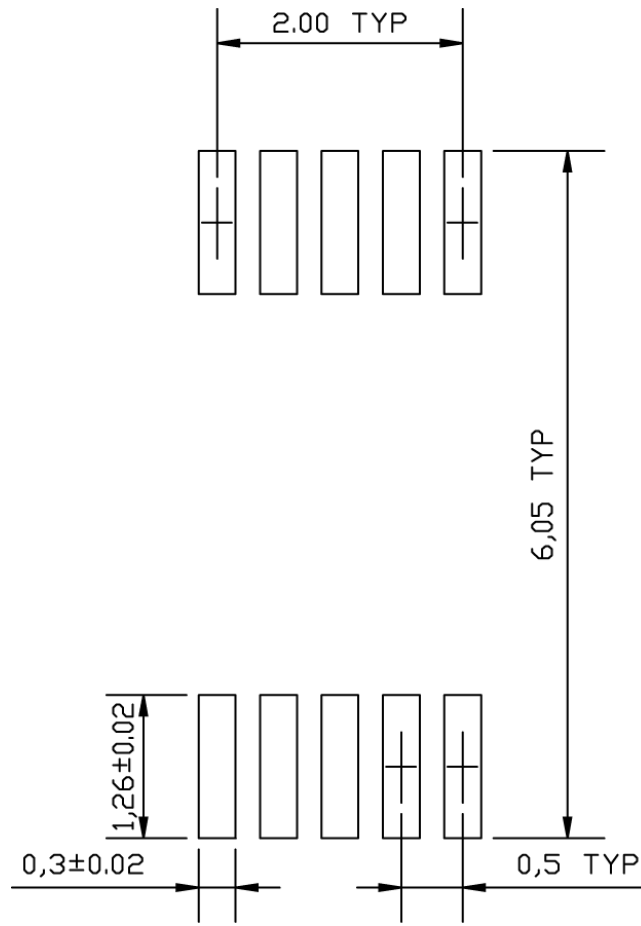
**Bill of Materials (MIC2164-3 12V to 1.8V @ 10A)**

| Item             | Part Number       | Manufacturer                   | Description   | Qty. |
|------------------|-------------------|--------------------------------|---|------|
| C1, C8, C17, C19 | 06035C104KAT      | AVX <sup>(1)</sup>             | 0.1 $\mu$ F Ceramic Capacitor, X7R, Size 0603, 50V  | 4    |
| C2               | 0805ZD225MAT      | AVX <sup>(1)</sup>             | 2.2 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V  | 1    |
| C3               | 222215095001      | Vishay <sup>(2)</sup>          | 220 $\mu$ F Aluminum Capacitor, SMD, 35V            | 1    |
| C4               | 1210YD106MAT      | AVX <sup>(1)</sup>             | 10 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 16V   | 1    |
| C9               | 0805ZD105KAT      | AVX <sup>(1)</sup>             | 1 $\mu$ F Ceramic Capacitor, X5R, Size 0805, 10V    | 1    |
| C10              | 06035C222KAT      | AVX <sup>(1)</sup>             | 2.2nF Ceramic Capacitor, X7R, Size 0603, 50V        | 1    |
| C11              | 6SEPC560MX        | Sanyo <sup>(3)</sup>           | 560 $\mu$ F OSCON Capacitor, 6.3V                   | 1    |
| C12              | 12106D107MAT      | AVX <sup>(1)</sup>             | 100 $\mu$ F Ceramic Capacitor, X5R, Size 1210, 6.3V | 1    |
| C15              | 06035C102KAT      | AVX <sup>(1)</sup>             | 1nF Ceramic Capacitor, X7R, Size 0603, 50V          | 1    |
| D1               | SD103BWS          | Vishay <sup>(2)</sup>          | Small Signal Schottky Diode                         | 1    |
| L1               | HCF1305-1R0       | Cooper Bussmann <sup>(4)</sup> | 1.0 $\mu$ H Inductor, 20A Saturation Current        | 1    |
| Q1, Q2           | FDS7764A          | Fairchild <sup>(5)</sup>       | 30V N-Channel MOSFET 7.5m $\Omega$ Rds(on) @ 4.5V   | 2    |
| R1               | CRCW06032R21FKEY3 | Vishay Dale <sup>(2)</sup>     | 2.21 $\Omega$ Resistor, Size 0603, 1%               | 1    |
| R5               | CRCW06031R21FKEY3 | Vishay Dale <sup>(2)</sup>     | 1.21 $\Omega$ Resistor, Size 0603, 1%               | 1    |
| R6               | CRCW06031002FKEY3 | Vishay Dale <sup>(2)</sup>     | 10k Resistor, Size 0603, 1%                         | 1    |
| R9               | CRCW06032001FKEY3 | Vishay Dale <sup>(2)</sup>     | 2k Resistor, Size 0603, 1%                          | 1    |
| R15              | CRCW06038061FKEY3 | Vishay Dale <sup>(2)</sup>     | 8.06k Resistor, Size 0603, 1%                       | 1    |
| U1               | MIC2164-3YMM      | Micrel, Inc. <sup>(6)</sup>    | 1MHz Buck Controller                                | 1    |
| U2               | MIC5233-5.0YM5    | Micrel, Inc. <sup>(6)</sup>    | LDO   | 1    |

**Notes:**

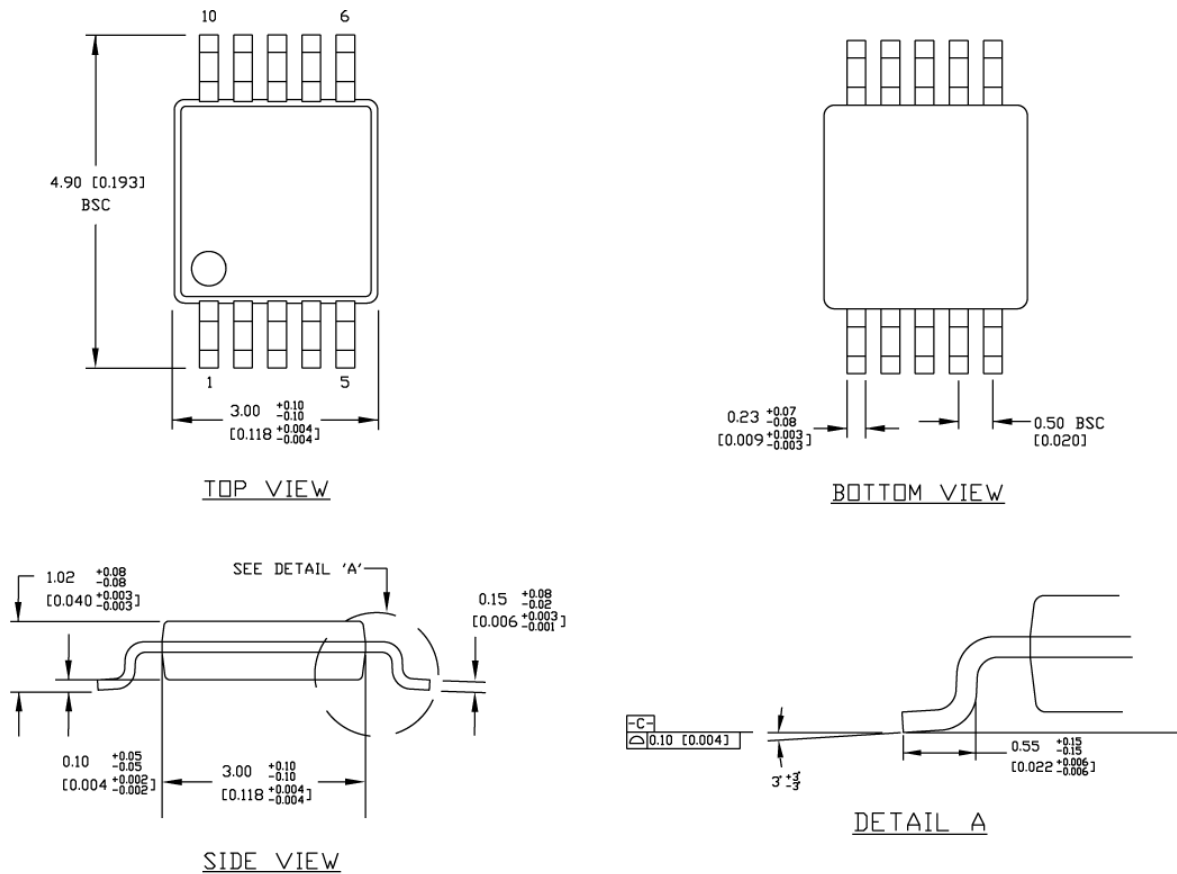
1. AVX: [www.avx.com](http://www.avx.com).
2. Vishay: [www.vishay.com](http://www.vishay.com).
3. Sanyo: [www.sanyo.com](http://www.sanyo.com).
4. Sumida: [www.sumida.com](http://www.sumida.com).
5. Fairchild: [www.fairchildsemi.com](http://www.fairchildsemi.com).
6. Micrel, Inc: [www.micrel.com](http://www.micrel.com).

### Recommended Land Pattern



10-Pin MSOP (MM)

## Package Information



**NOTES:**

1. DIMENSIONS ARE IN MM [INCHES].
2. CONTROLLING DIMENSION: MM
3. DIMENSION DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS, EITHER OF WHICH SHALL NOT EXCEED 0.20 [0.008] PER SIDE.

### 10-Pin MSOP (MM)

**MICREL, INC. 2180 FORTUNE DRIVE SAN JOSE, CA 95131 USA**  
 TEL +1 (408) 944-0800 FAX +1 (408) 474-1000 WEB <http://www.micrel.com>

Micrel makes no representations or warranties with respect to the accuracy or completeness of the information furnished in this data sheet. This information is not intended as a warranty and Micrel does not assume responsibility for its use. Micrel reserves the right to change circuitry, specifications and descriptions at any time without notice. No license, whether express, implied, arising by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Micrel's terms and conditions of sale for such products, Micrel assumes no liability whatsoever, and Micrel disclaims any express or implied warranty relating to the sale and/or use of Micrel products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright or other intellectual property right.

Micrel Products are not designed or authorized for use as components in life support appliances, devices or systems where malfunction of a product can reasonably be expected to result in personal injury. Life support devices or systems are devices or systems that (a) are intended for surgical implant into the body or (b) support or sustain life, and whose failure to perform can be reasonably expected to result in a significant injury to the user. A Purchaser's use or sale of Micrel Products for use in life support appliances, devices or systems is a Purchaser's own risk and Purchaser agrees to fully indemnify Micrel for any damages resulting from such use or sale.

© 2009 Micrel, Incorporated.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А